

SMR 1232 - 13

**XII WORKSHOP ON
STRONGLY CORRELATED ELECTRON SYSTEMS**

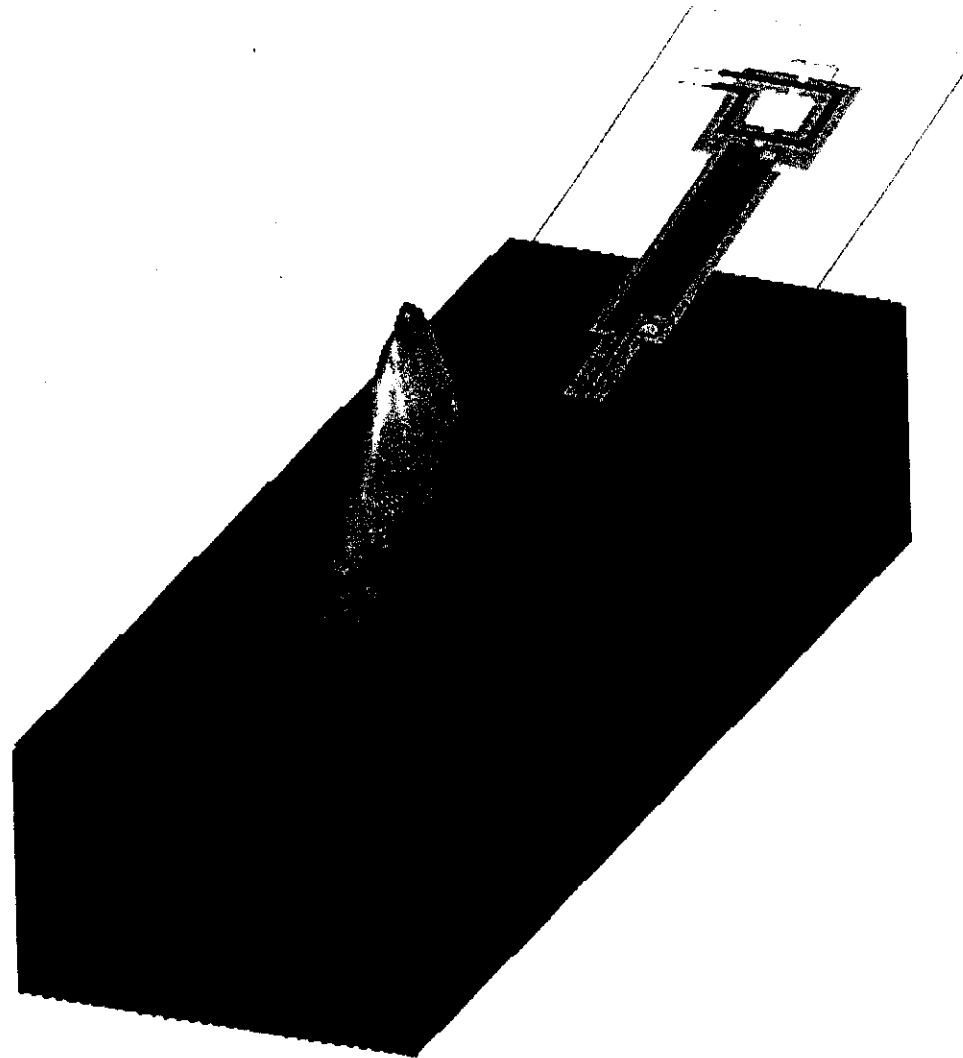
17 - 28 July 2000

***SCANNING SQUID MICROSCOPY
AND SUSCEPTOMETRY***

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These are preliminary lecture notes, intended only for distribution to participants.

Scanning SQUID microscopy and susceptometry



-1-

COLLABORATORS

IBM J.R. Kirtley, C.C. Tsuei, M. Ketchen, M. Bhushan

Argonne

$Tl_2Ba_2CuO_{6+\delta}$

T.W. Li, M. Xu, D. Hinks

Groningen

$Tl_2Ba_2CuO_{6+\delta}$

N. Kolesnikov, D. vander Marel, A. Tsvetkov

Caen

$(Hg, Cu)Ba_2CuO_{4+\delta}$

G. Villard, A. Maignan

Tokyo

$La_{2-x}Sr_xCuO_4$

M. Nohara, H. Takagi

ISU/Ames

I.L.J.V. Theory

V. Kogan, J. Clem

Princeton

N.P. Ong, P.W. Anderson, P. Chaikin

Stanford

P. Bjornsson, B. Gardner,
E. Straver, J. Wynn

OUTLINE

Scanning SQUID Microscopy

Josephson Vortices in YBCO

$\frac{1}{2} \Phi_0(T)$ in tricrystals

$\lambda_J(T)$

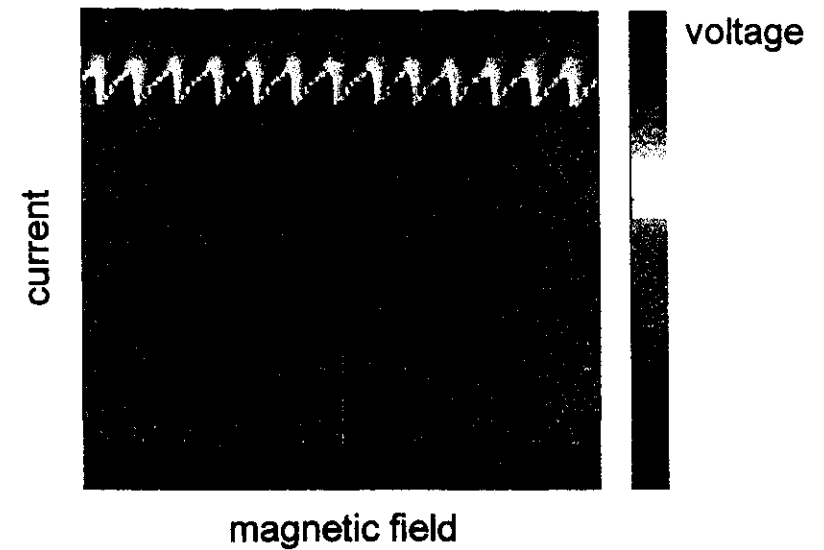
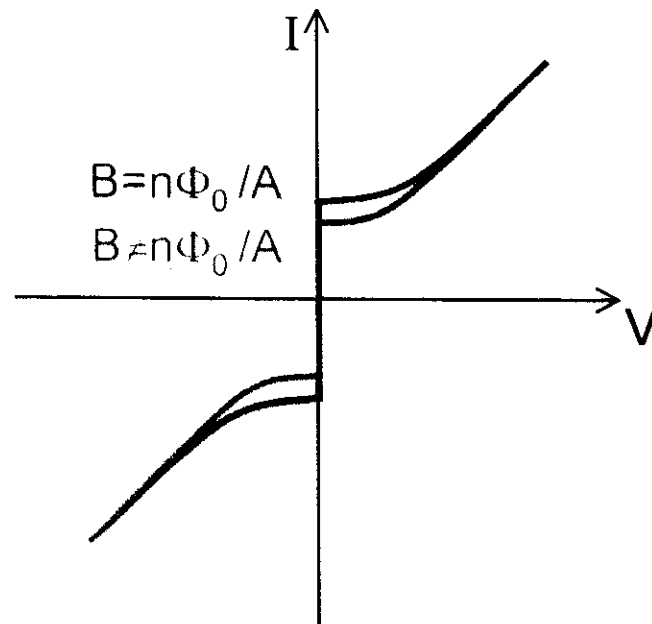
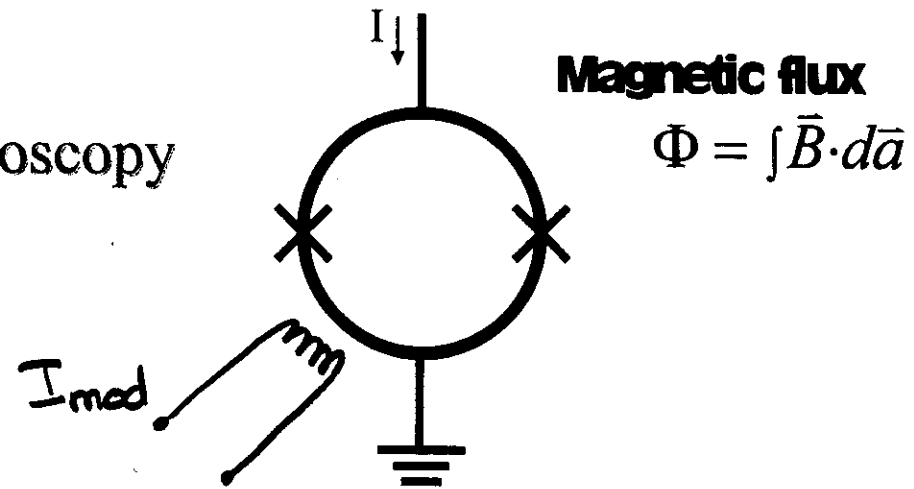
Interlayer Josephson Vortices

λ_c and inter layer tunneling

Inter Layer Tunneling (ILT)

Scanning SQUID Susceptometry

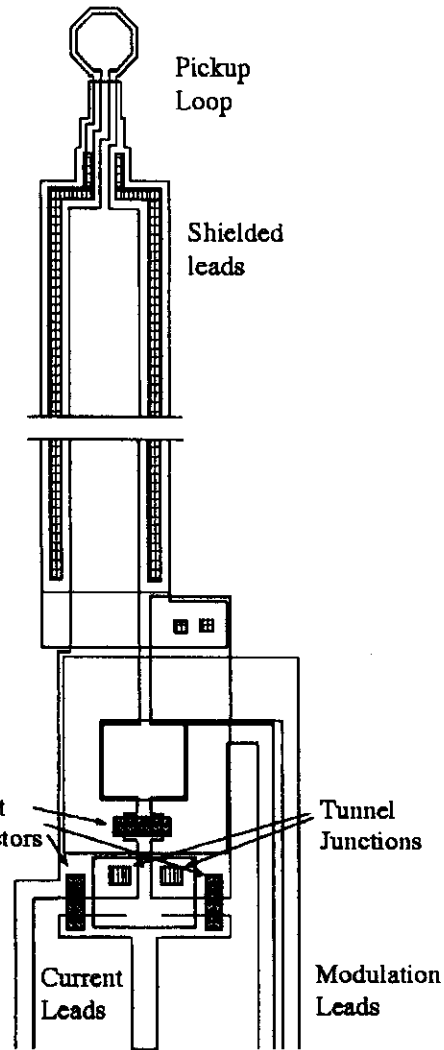
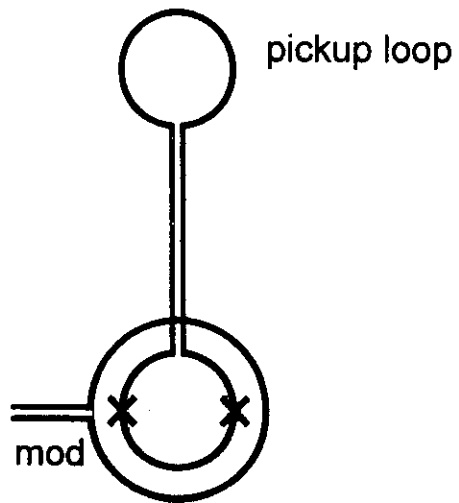
Scanning SQUID Microscopy



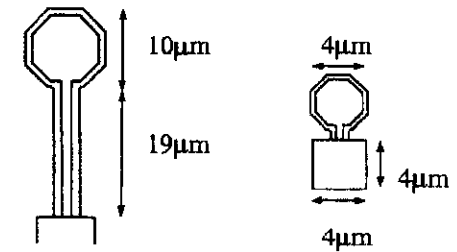
SQUID characterization:
Brian Gardner, Jennifer Hsieh

Scannable SQUID

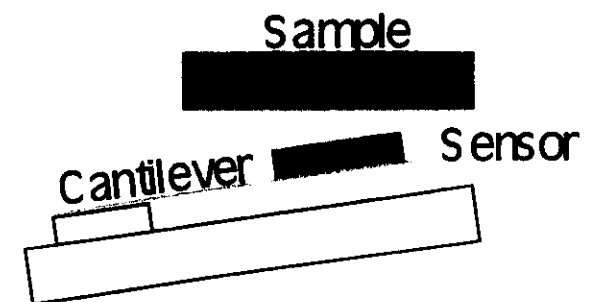
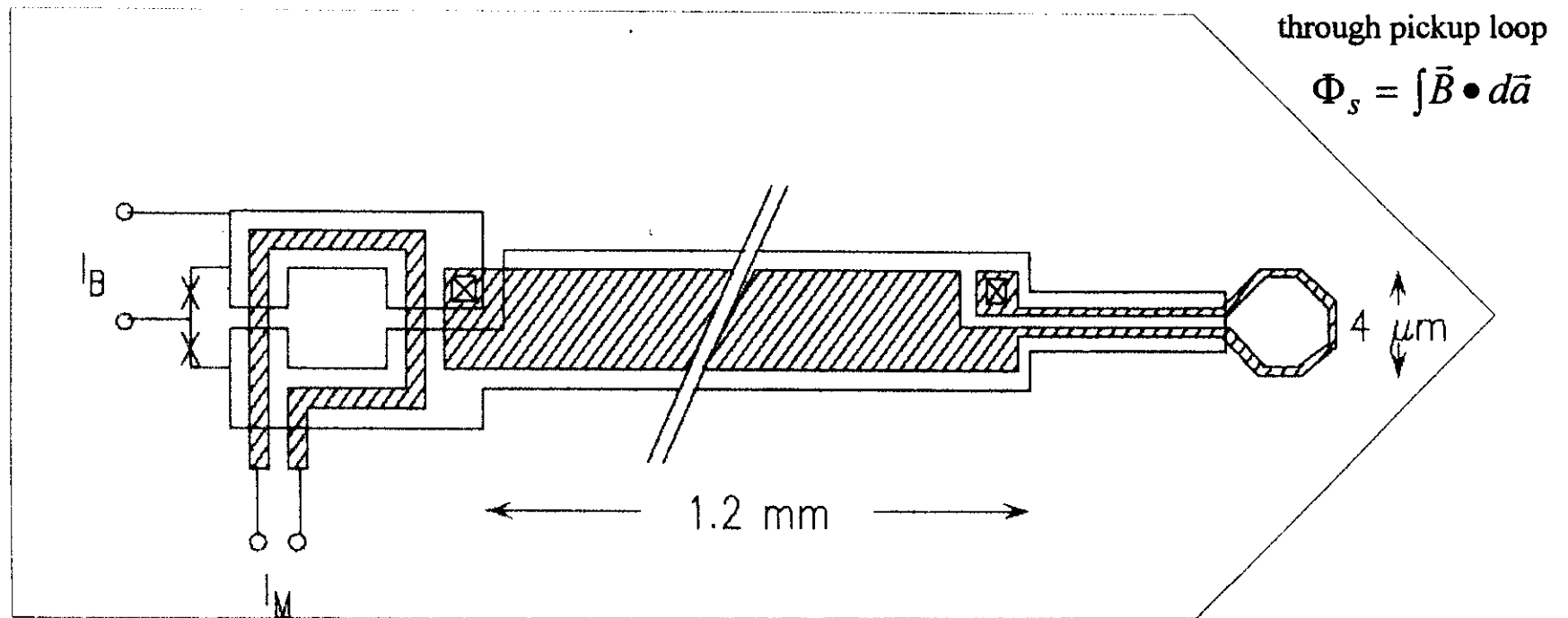
schematic



pickup loop designs

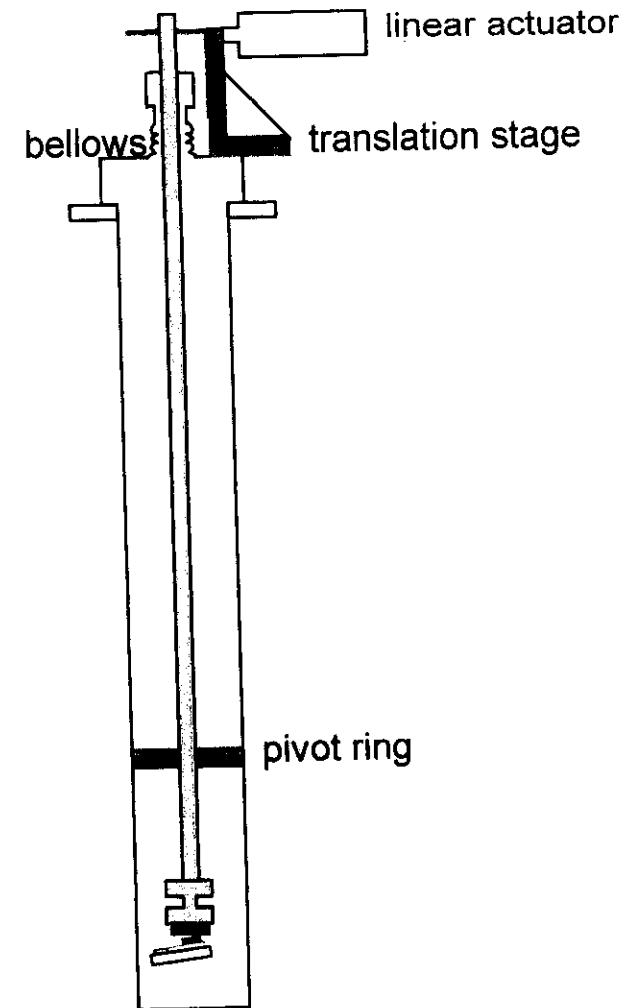
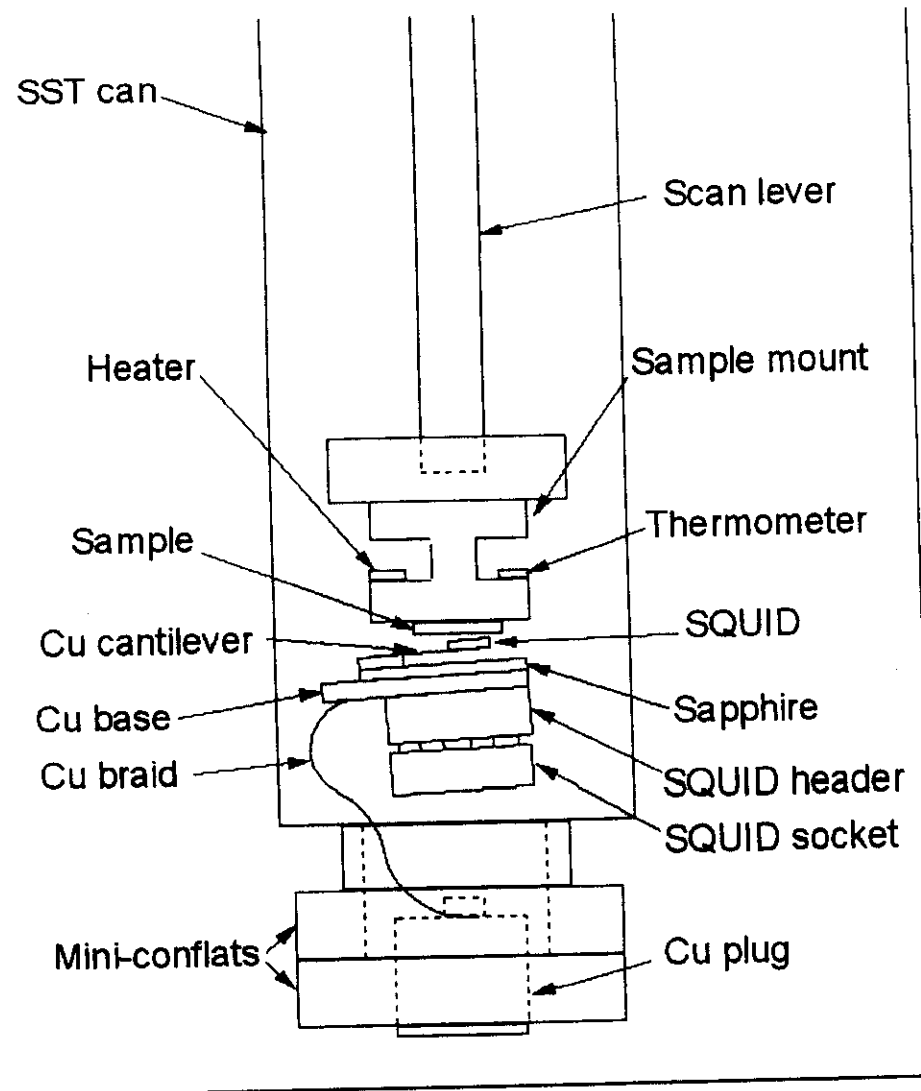


Scanning Something-on-a-Chip Microscopy



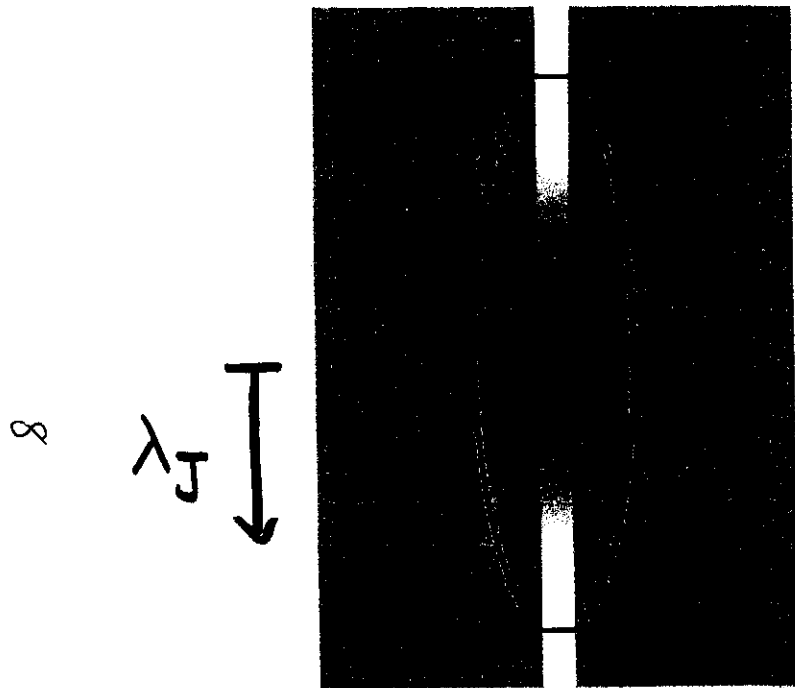
IBM Scanning SQUID Microscope: Variable sample temperature mechanical scanner

Sensor at ~ 10 K
Sample up to 150 K
cm scan range



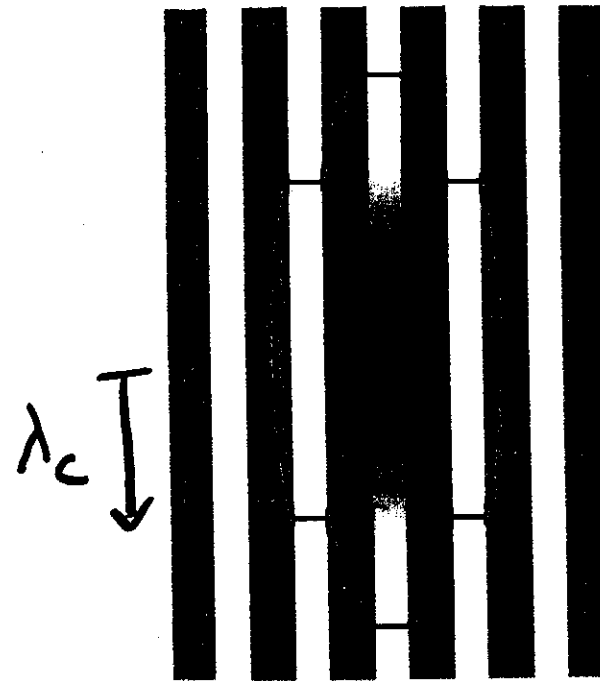
Types of Josephson vortices

Josephson vortex



$$b_z(0, y) = \frac{4\pi\Phi_0}{d\lambda_J} \text{sech}(y/\lambda_J)$$

Interlayer Josephson vortex



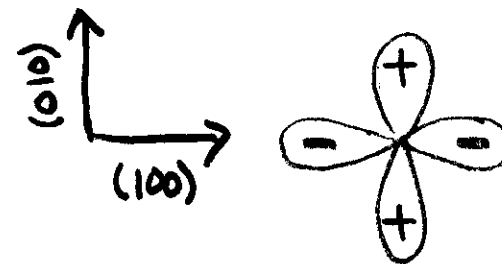
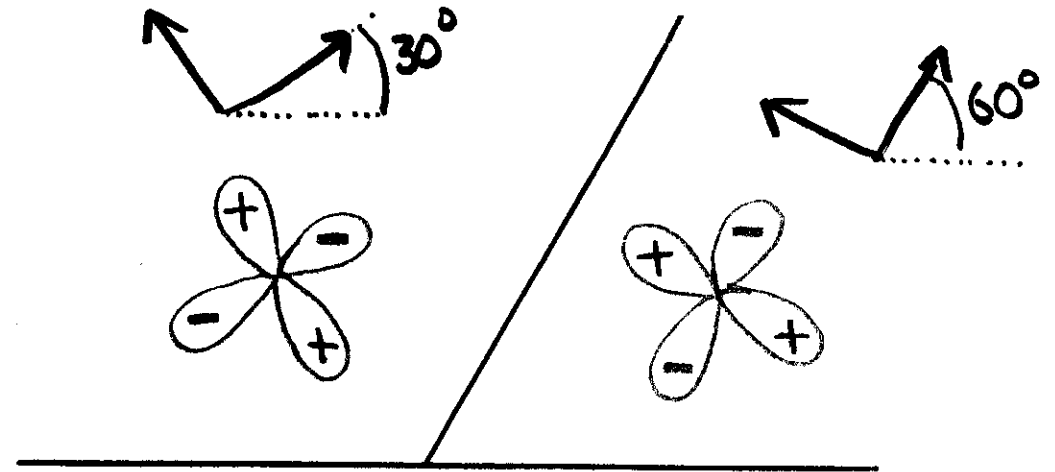
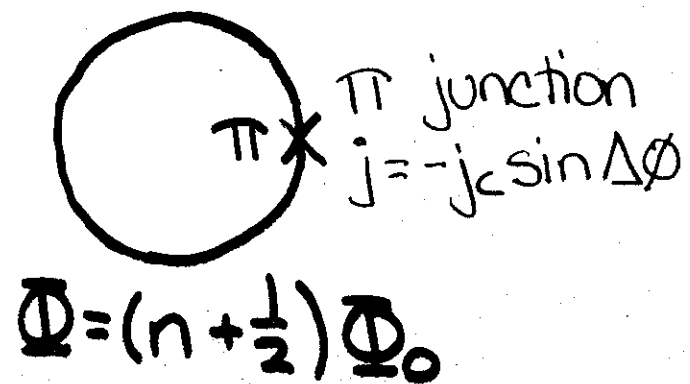
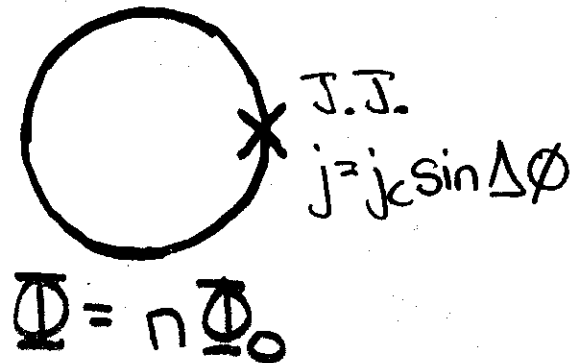
$$b_z(x, y) = \frac{\Phi_0}{2\pi\lambda_{ab}\lambda_c} K_0(\tilde{R})$$

$$\tilde{R} = \sqrt{\left(\frac{s}{2\lambda_{ab}}\right)^2 + \left(\frac{x}{\lambda_{ab}}\right)^2 + \left(\frac{y}{2\lambda_c}\right)^2}$$

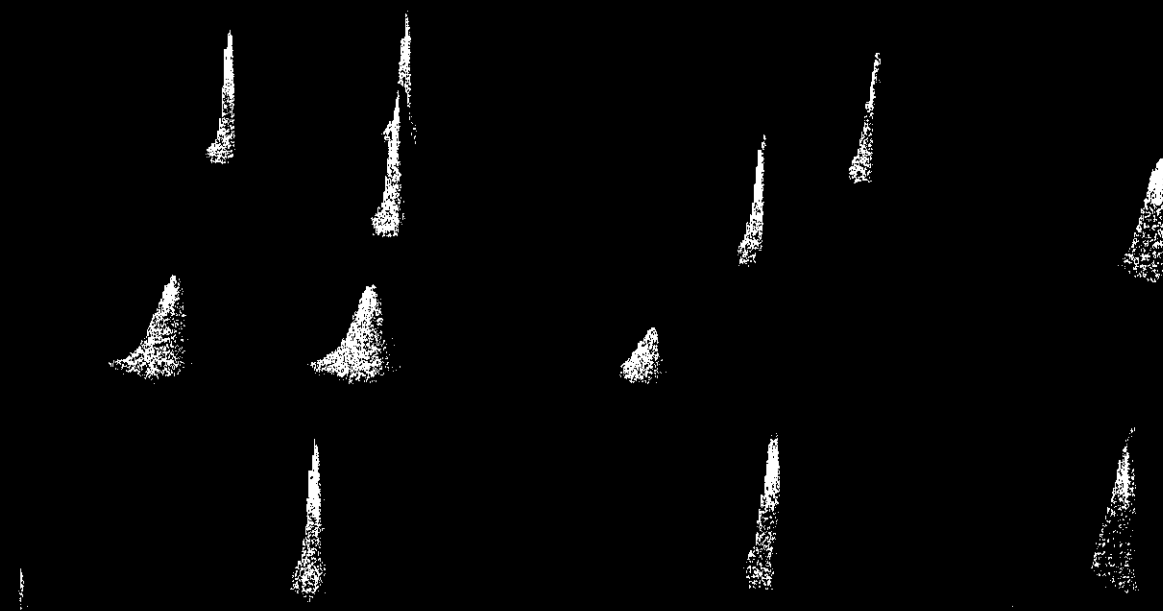
Lawrence & Doniach 1971

Coffey & Clem 1990

Half-Integral Flux Quantization



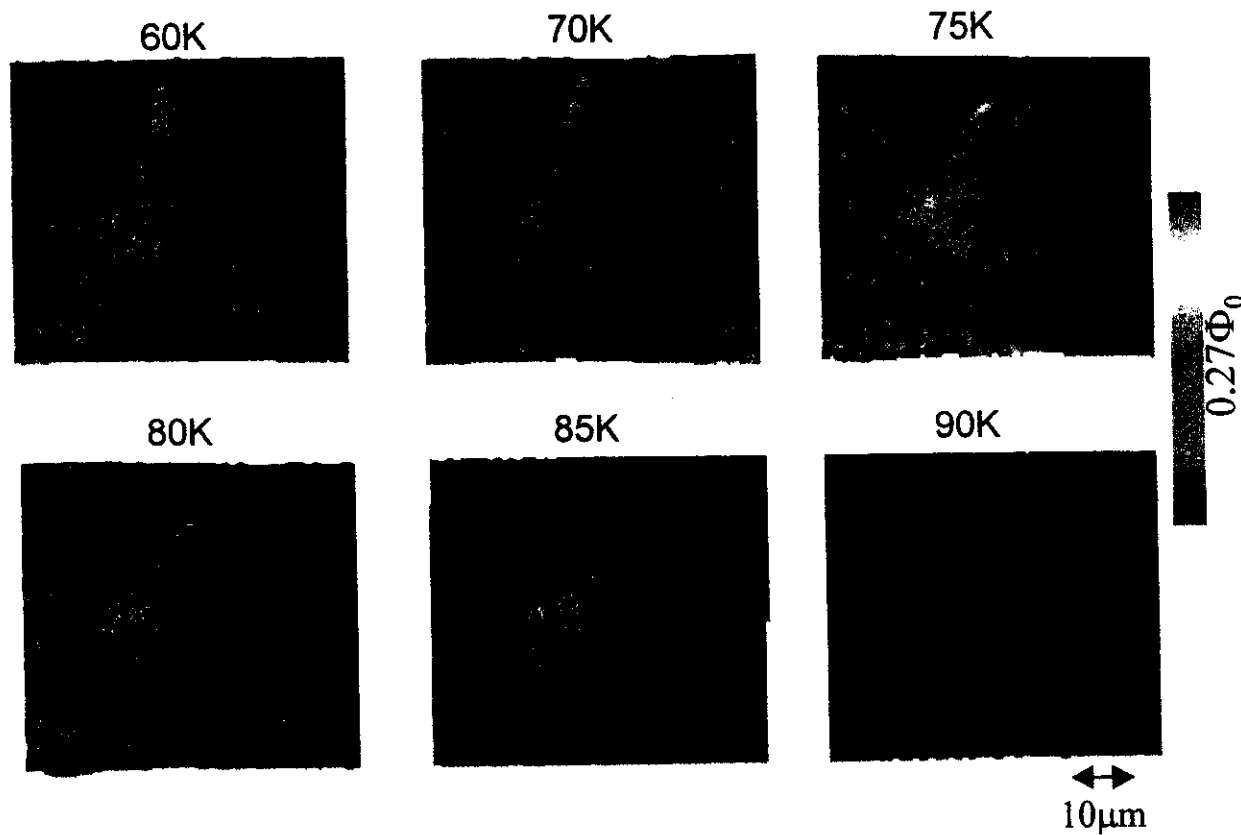
Integral Vortices and Half-Integral Vortex in Tricrystal YBCO



100 μm

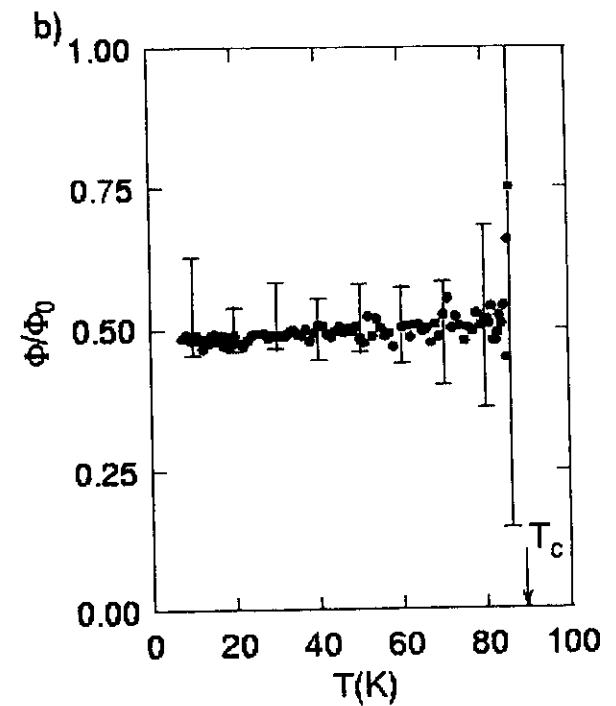
YBaCuO_{7-x} film on SrTiO₃ (magnified 100 $\times$)
Scanning SQUID microscopy image at 4.2 K

Temperature dependence of the half-integral flux quantum in YBCO



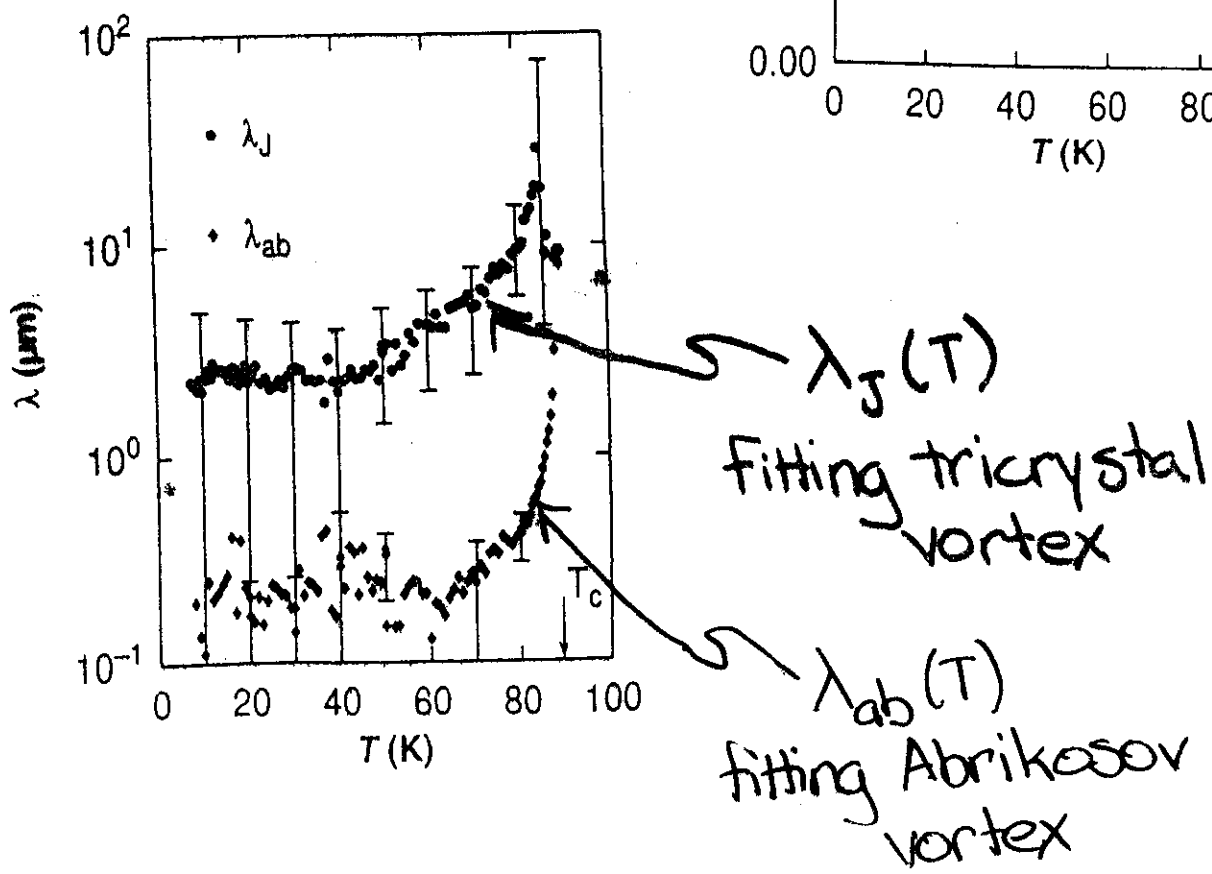
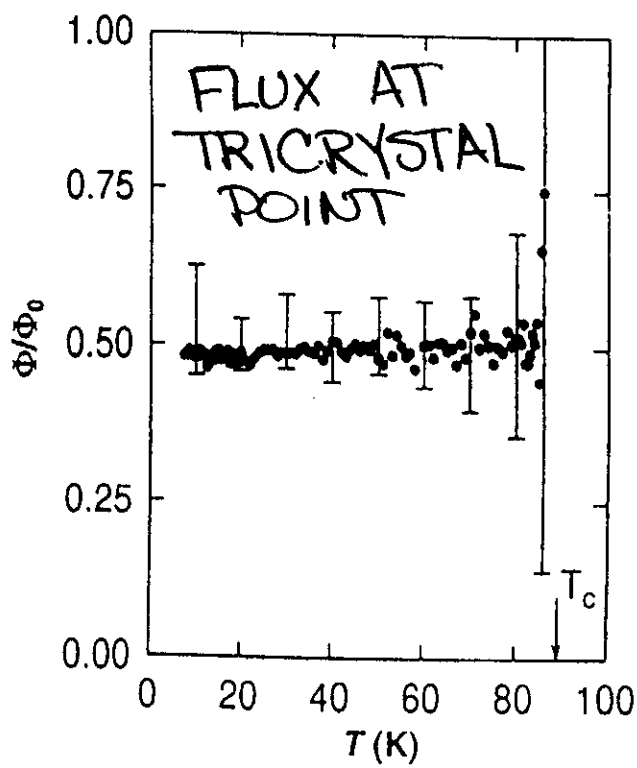
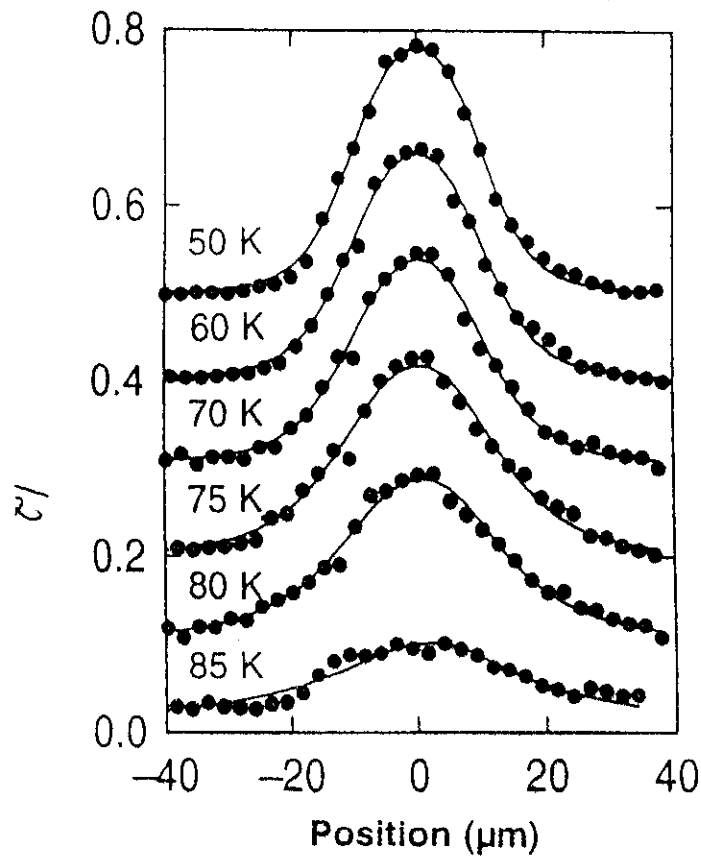
$$\Phi_{\text{trixtal}} = \frac{\Phi_0}{2}$$

for $0.4\text{K} \leq T \leq 88\text{K}$

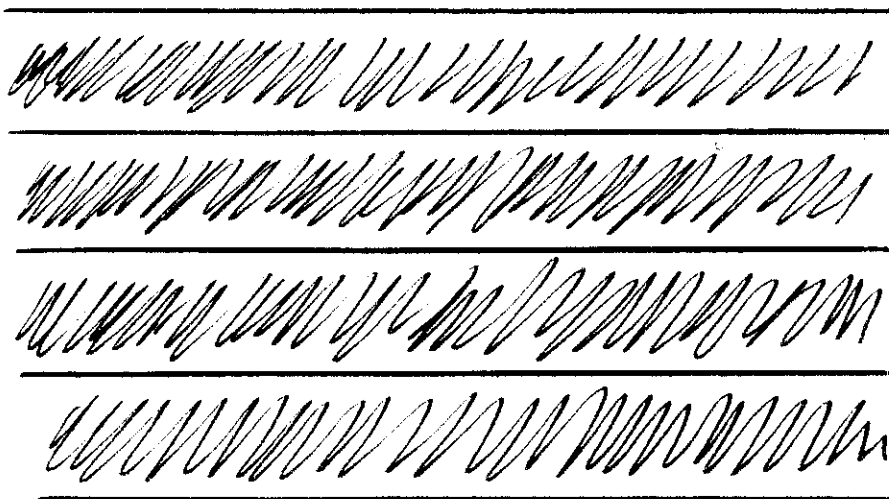


Kirtley, Tsuei, and Moler
1999

HORIZONTAL CROSS-SECTIONS



CuO_2
stuff



Josephson
Tunneling

Lawrence-Doniach Model

Intrinsic Tunneling in $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ Mesas

10 layers $3.5\mu \times 7.5\mu$

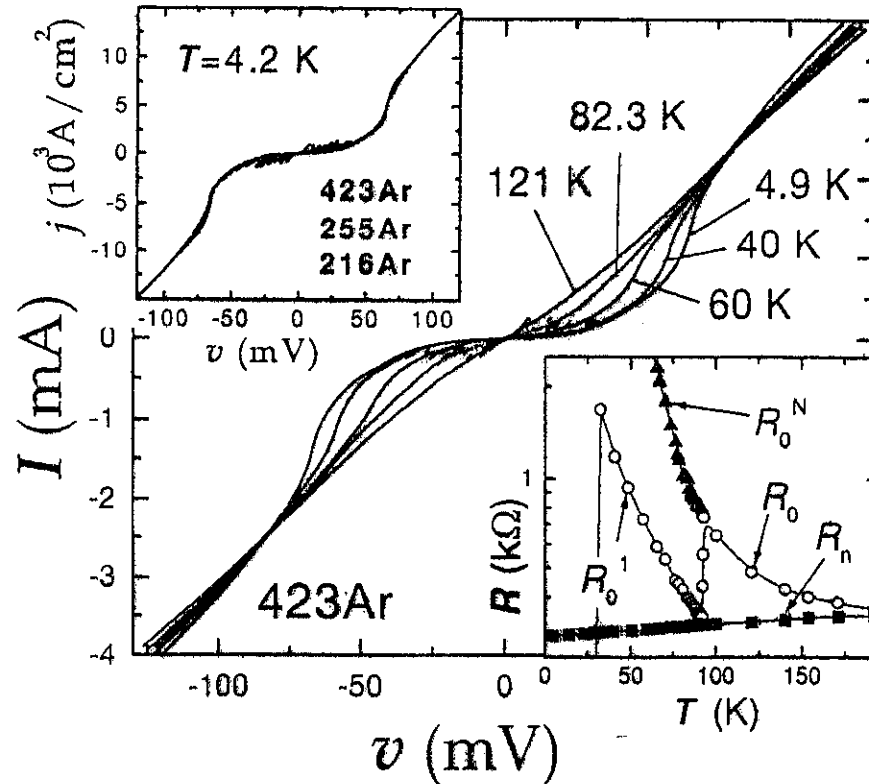


FIG. 1. I - v curves for the 423Ar mesa at different T . Top inset shows normalized I - V curves at $T = 4.2$ K for three different mesas. Bottom inset shows in the logarithmic scale temperature dependencies of the zero bias resistance R_0 (open circles), large bias resistance R_n (solid squares) and the total subgap resistance R_0^N (solid triangles).

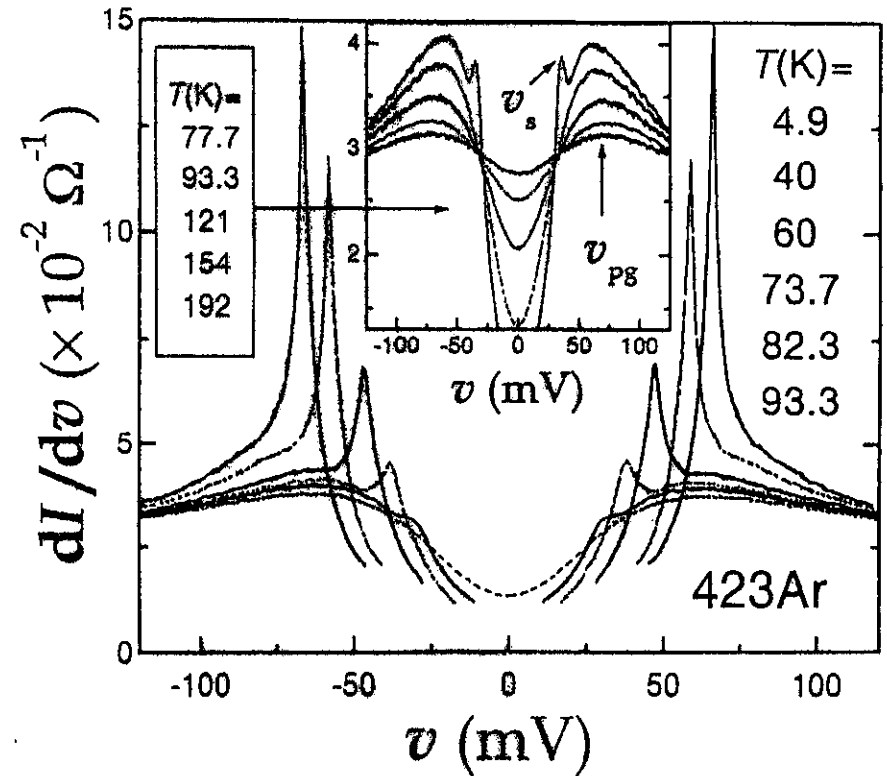
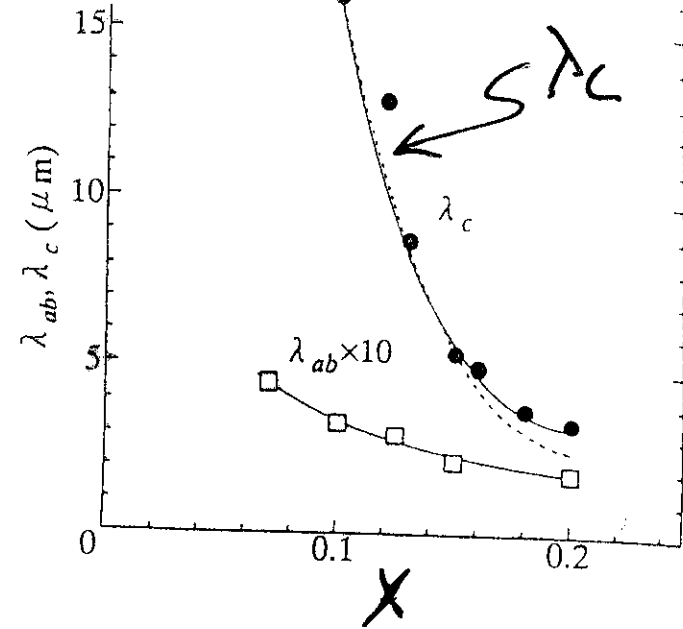
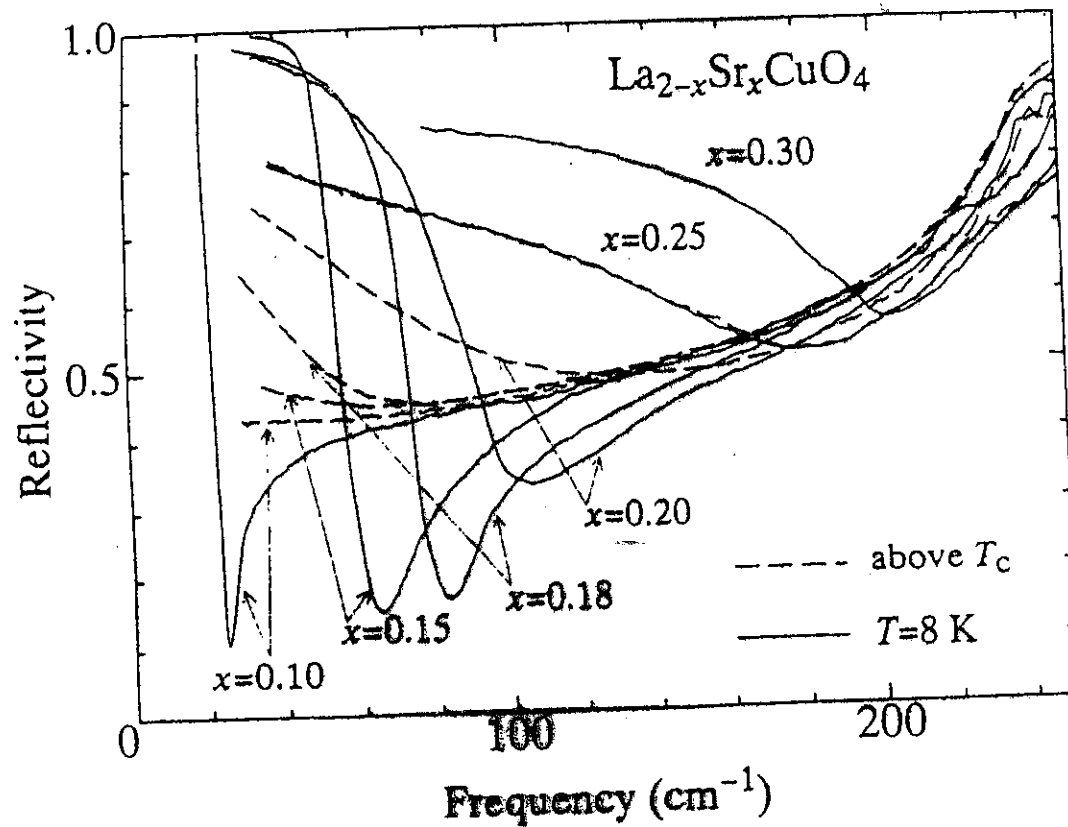


FIG. 2. Dynamic conductance, $\sigma(v)$, at different temperatures for 423Ar mesa. Inset shows detailed curves for high T . Co-existence of the superconducting peak, v_s , and the pseudogap hump, v_{pg} , is clearly visible at $T = 77.7$ K.

Krishna Yimons Winkler Delsing Choe 2000

Josephson Plasma Resonance in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$

Uchida, Tamasaku, and Tajima



$$\omega_J = \frac{c}{\sqrt{\epsilon} \lambda_c}$$

Ambegaokar-Baratoff model

applied to c-axis tunneling

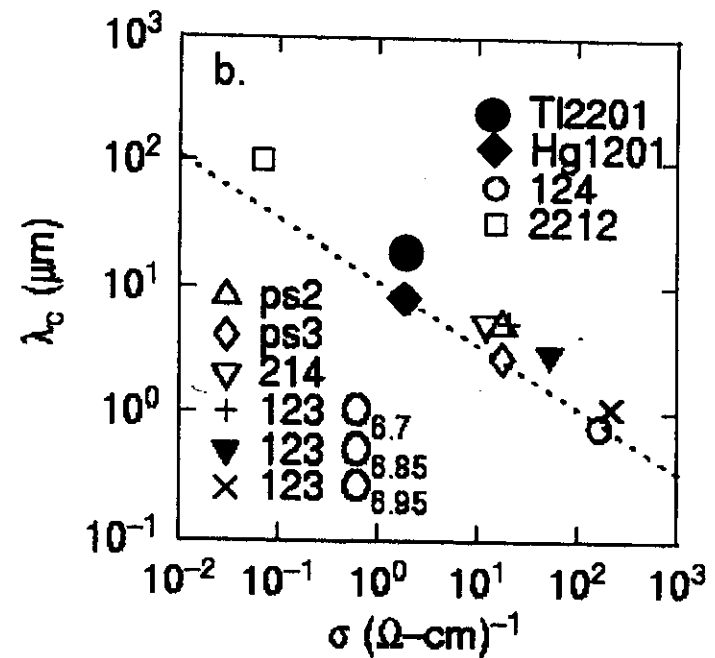
$$\lambda_c = \sqrt{\frac{c\Phi_0}{8\pi^2 s J_0}}$$

Ambegaokar-Baratoff

$$J_0 = \frac{\pi\Delta_0}{2e\rho_{c,n}}$$

problems

- what's $\rho_{c,n}(T=4K, H \approx 0)$?
- anisotropic gap
- effective mass

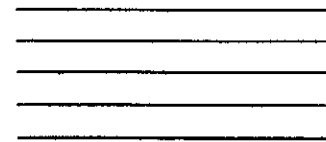


Basov 1994

Inter-Layer Tunneling Model*

J.W. Wheatley, T. Hsu, P.W. Anderson, 1988.

S. Chakravarty, A. Subdø, P.W. Anderson, S. Strong, 1993.



* The ILT mechanism should not be confused with interlayer tunneling.

Experimental test as formulated by A.J. Leggett 1996

(motivated by Groningen experiment)

$$\lambda_c = \frac{\lambda_{ILT}}{2\eta^{1/2}} \quad \text{where} \quad \lambda_{ILT} = \sqrt{\frac{mc^2}{E_c} \frac{a_0 A}{4\pi d}}$$

fraction of condensation energy

which comes from kinetic energy savings

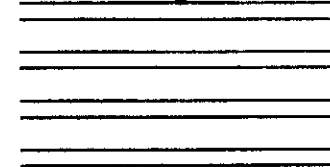
Single-layer high-T_c materials make the most straightforward test

Tl-2201 $\lambda_{ILT} \approx 1 \mu\text{m}$

Hg-1201 $\lambda_{ILT} \approx 1 \mu\text{m}$

LSCO $\lambda_{ILT} \approx 3 \mu\text{m}$

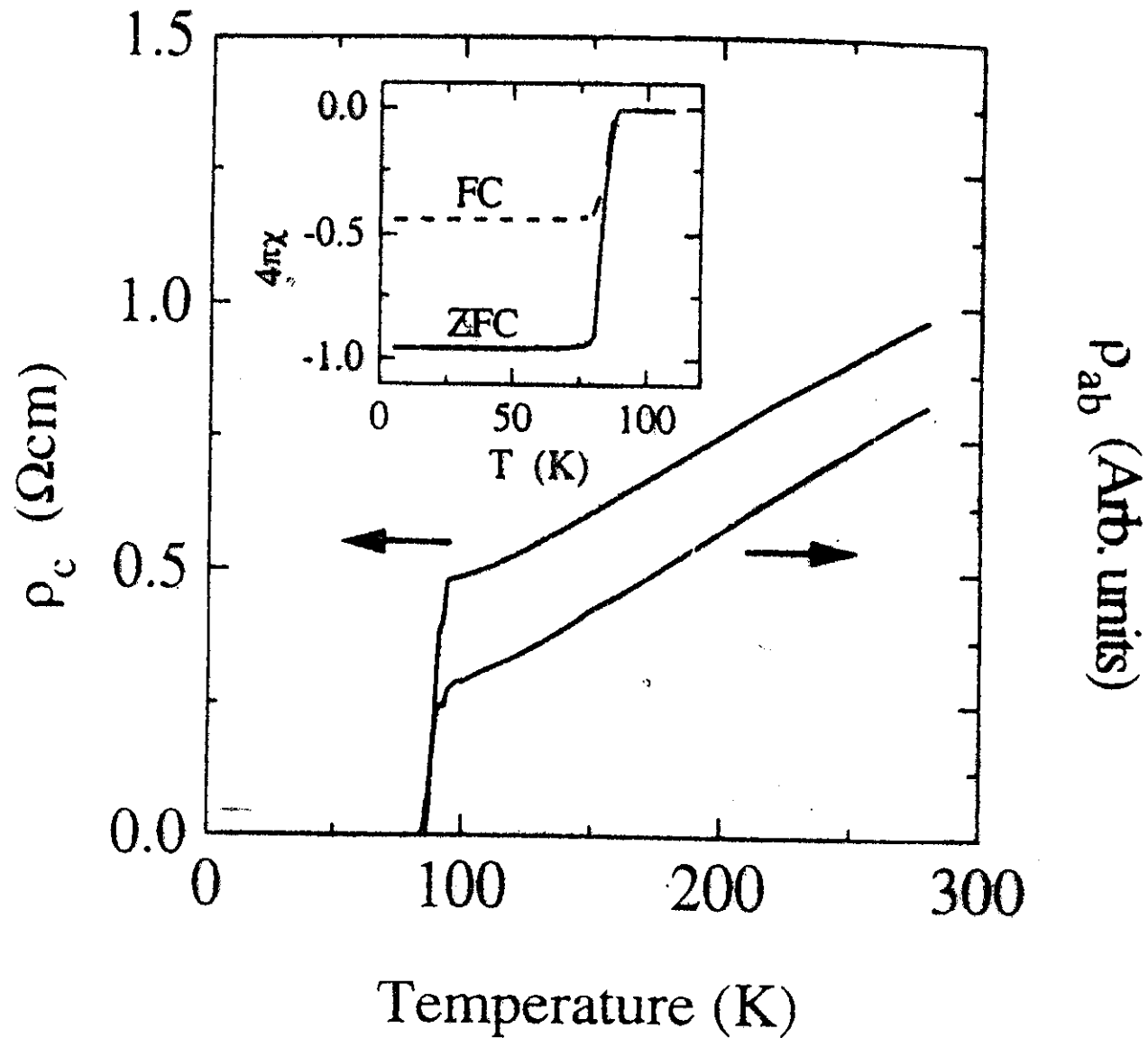
bilayer



Josephson plasma frequency $\omega_p = \frac{c}{\lambda_c}$

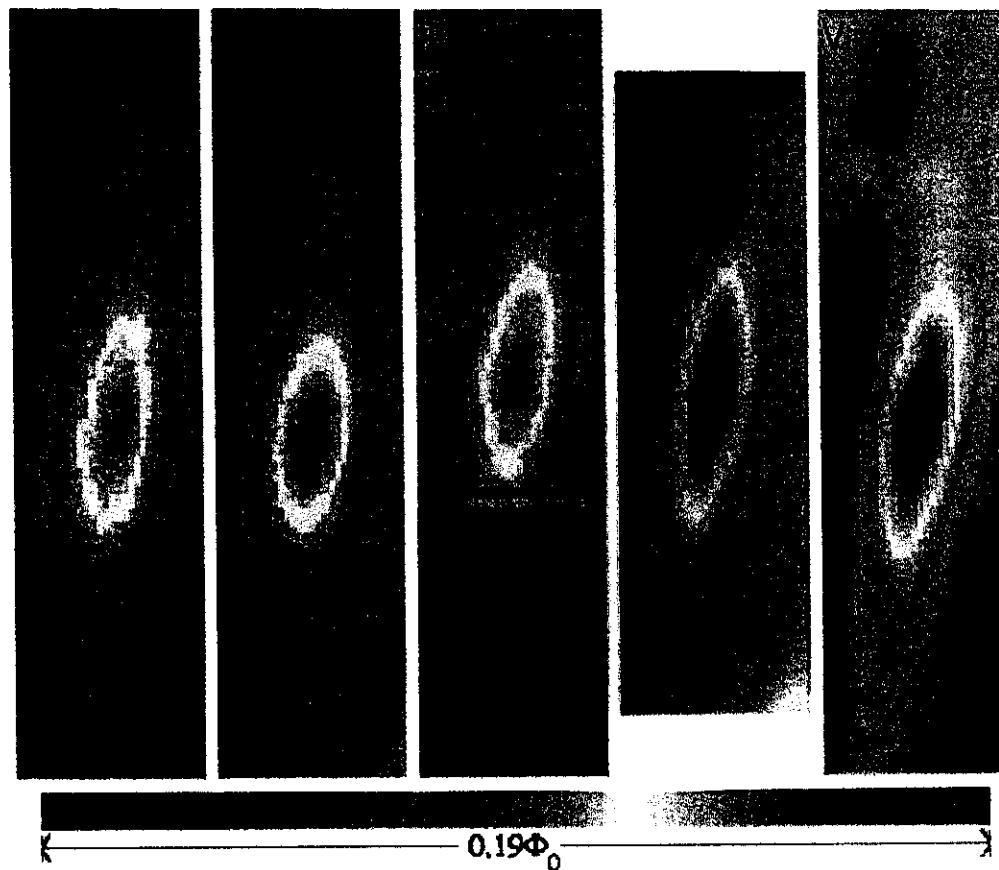
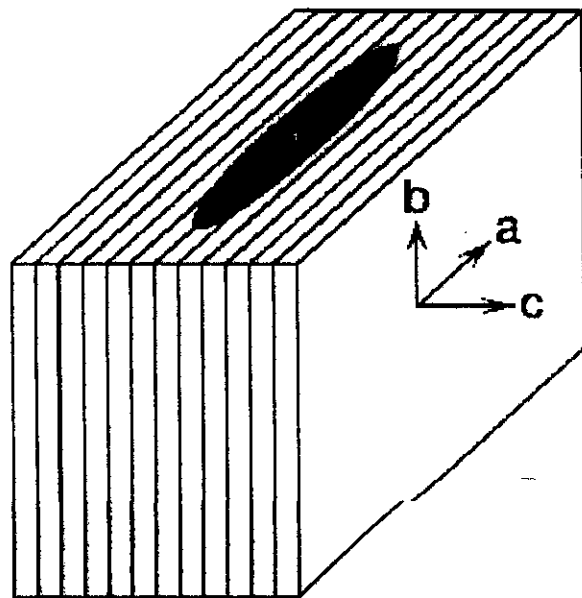
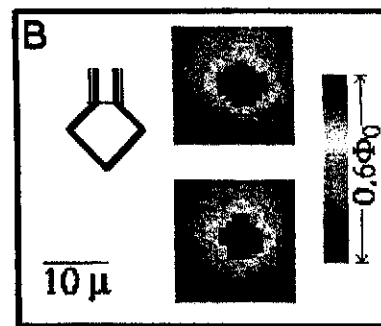
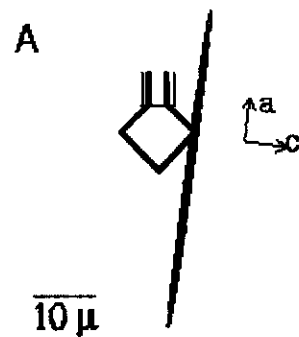
van der Marel and coworkers 1995 Tl-2201 $\omega_p < 100\text{cm}^{-1} \Rightarrow \lambda_c > 15 \mu\text{m}$

Resistivity of Tl-2201 single Crystal



Schützmann et al, 1997.

Tl-2201 raw data



Quantitative Modeling

1st try Full Width Half Maximum

2nd try Neglect spreading below surface (wrong!) and integrate over SQUID pickup loop shape

$$b_z(x, y) = \frac{\Phi_0}{2\pi\lambda_{ab}\lambda_c} K_0 \left(\sqrt{(s/2\lambda_{ab})^2 + (x/\lambda_{ab})^2 + (y/\lambda_c)^2} \right)$$

- propagate fields to height z_0
- integrate over pickup loop
- 2 free parameters: λ_c and z_0

3rd try Solve the anisotropic London model at a superconductor-vacuum interface and integrate over the known SQUID pickup loop shape

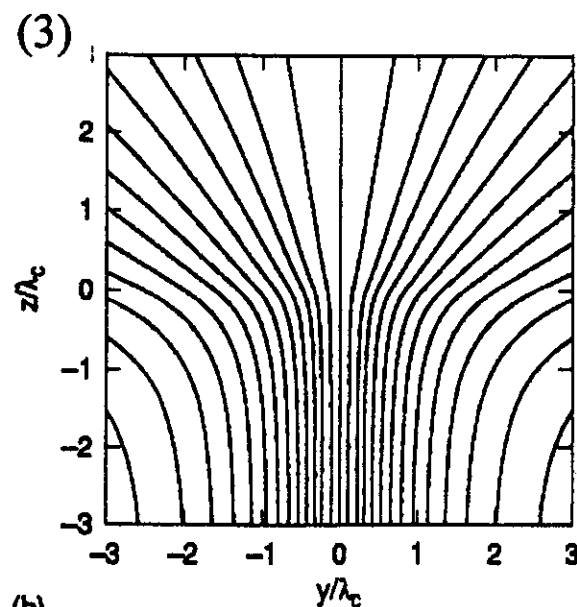
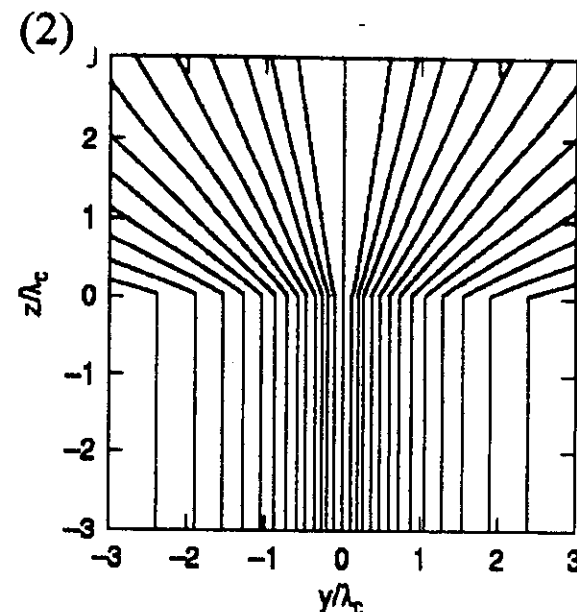
$$b_z(x, y) = - \int k \varphi(k) e^{i\vec{k} \cdot \vec{r} - kz} \frac{d^2 k}{(2\pi)^2}$$

$$\text{where } \varphi(\vec{k}) = \frac{-\Phi_0(1 + m_1 k_x^2)}{m_3 \alpha_3 (m_1 k_x^2 \alpha_3 (k + \alpha_1) + k \alpha_3 + k_y^2)}$$

$$\text{and } \alpha_1 = \sqrt{\frac{1 + m_1 k^2}{m_1}} \text{ and } \alpha_3 = \sqrt{\frac{1 + m_1 k_x^2 + m_3 k_y^2}{m_3}}$$

- evaluate integrals at height z_0
- integrate over pickup loop
- 2 free parameters: λ_c and z_0

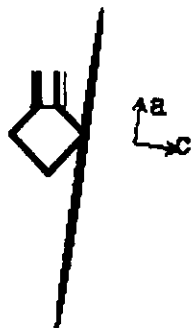
caveat: Farid



(b)

Tl-2201

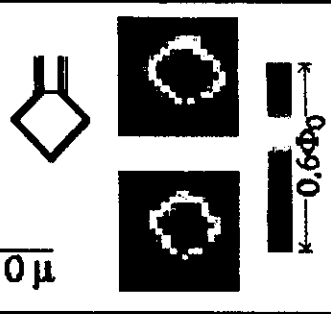
A



10μ



B

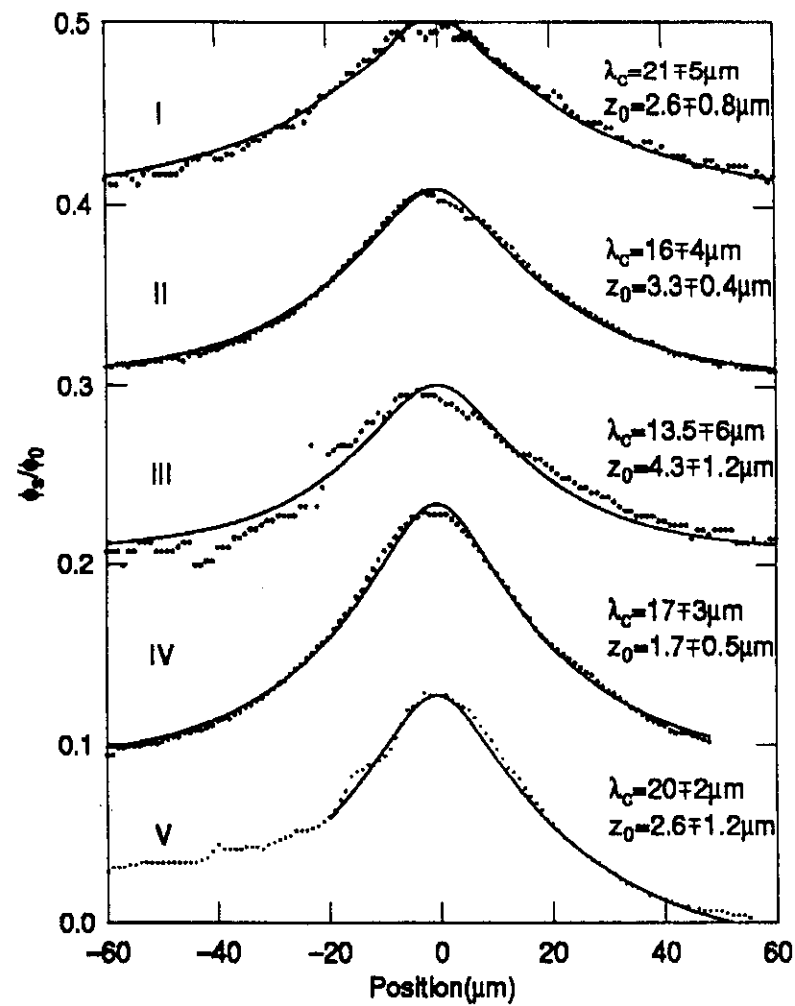


10μ

$0.6\Phi_0$



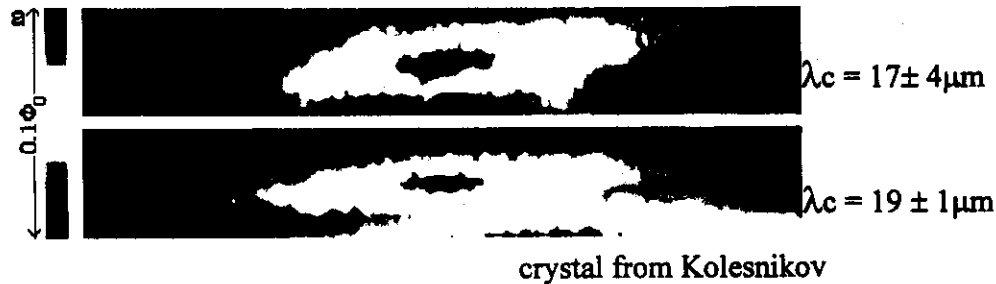
$0.19\Phi_0$



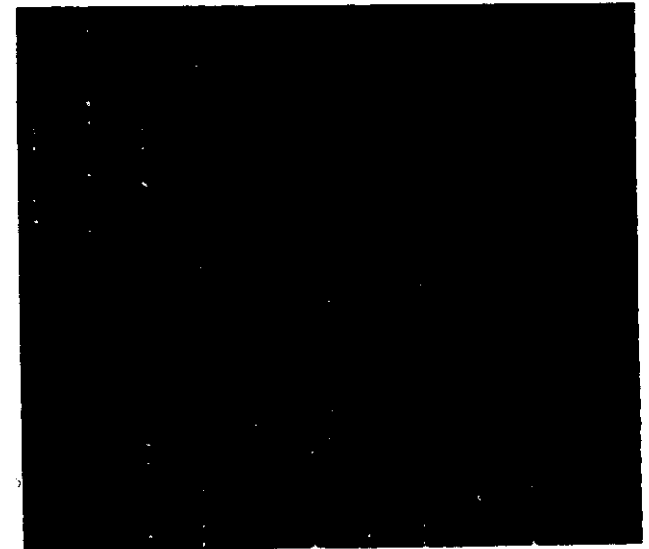
$$\lambda_c \approx 18 \pm 3 \mu\text{m}$$

Are we measuring the intrinsic penetration depth in Tl-2201?

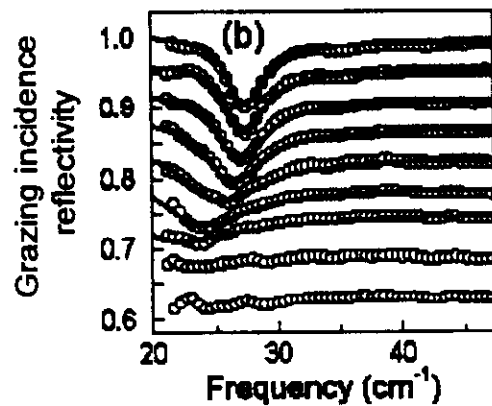
Vortices in 3 crystals from 2 groups
gives consistent results with
scanning SQUID microscopy.



No evidence for stacking
faults or superlattice structure
in TEM or x-ray.

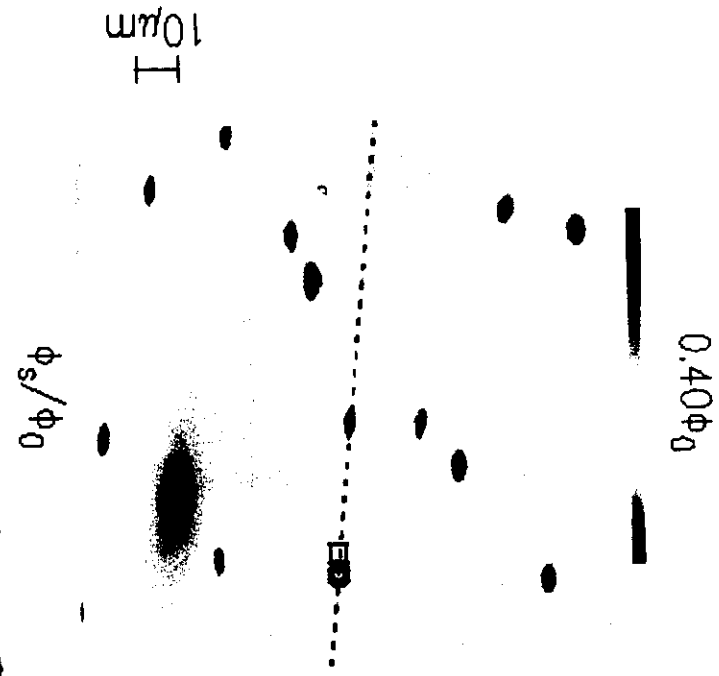


Optical techniques give consistent results.

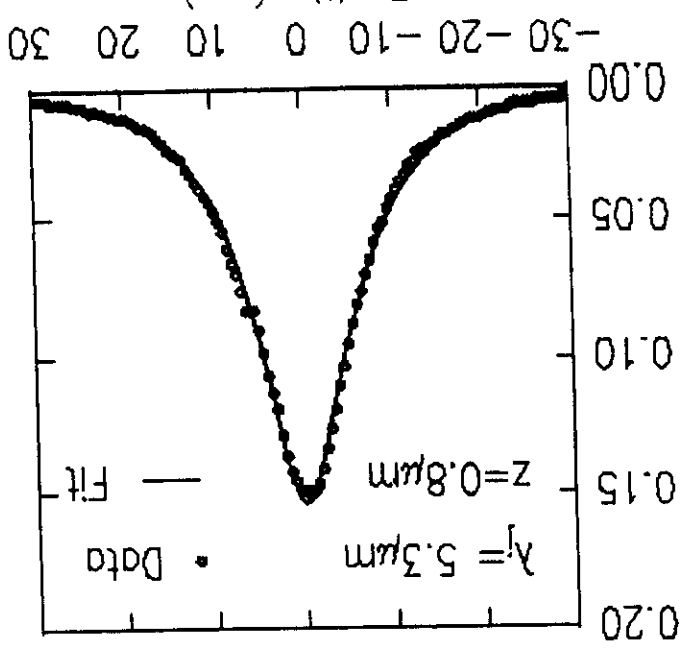
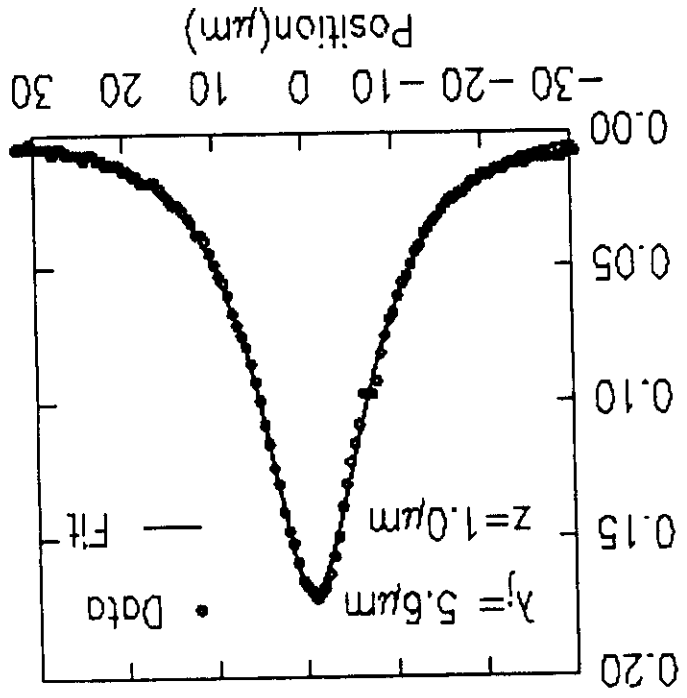
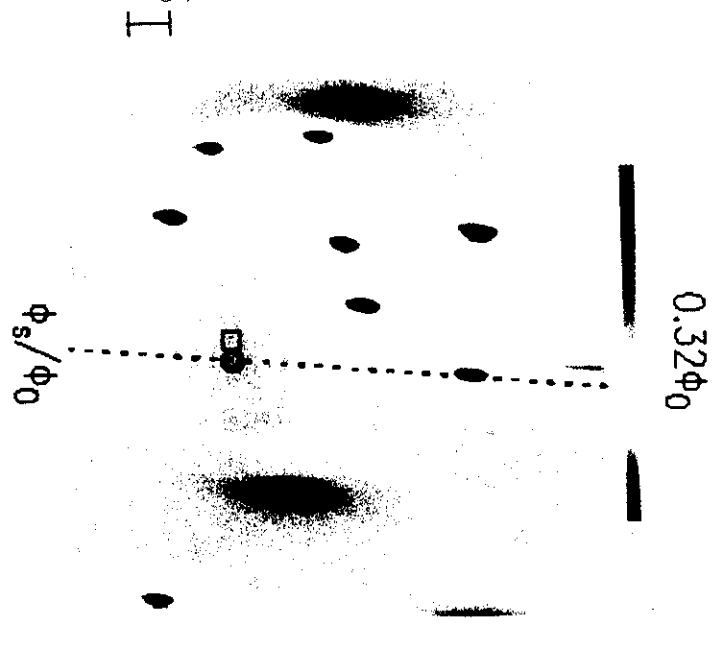


$\lambda_c = 17 \mu\text{m}$ Tsvetkov et al 1998 (thin films from Ren's group)
 $\lambda_c = 12 \mu\text{m}$ Basov et al 1999 (crystals from Hinks)

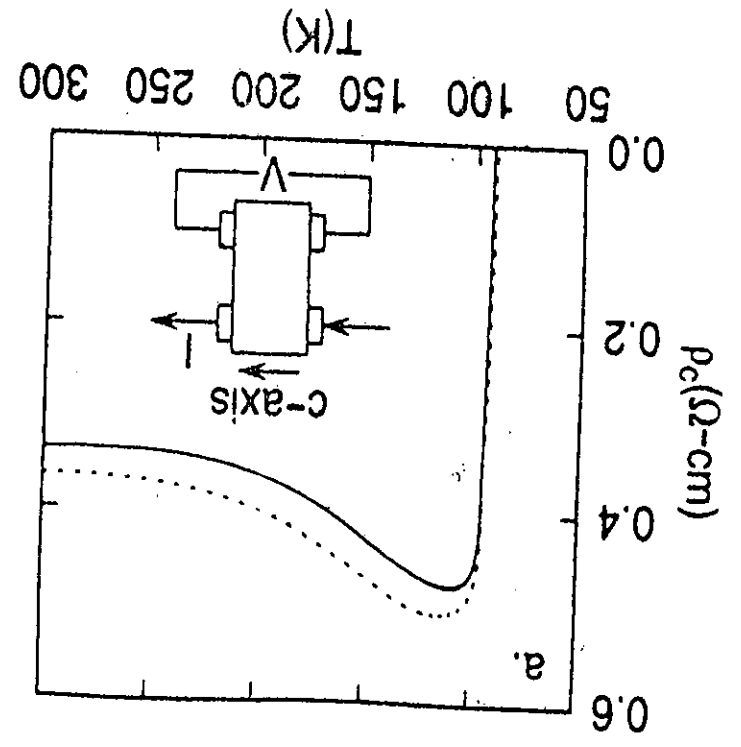
$\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$

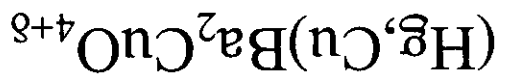


$\lambda_c \approx 5 \pm 1 \mu\text{m}$



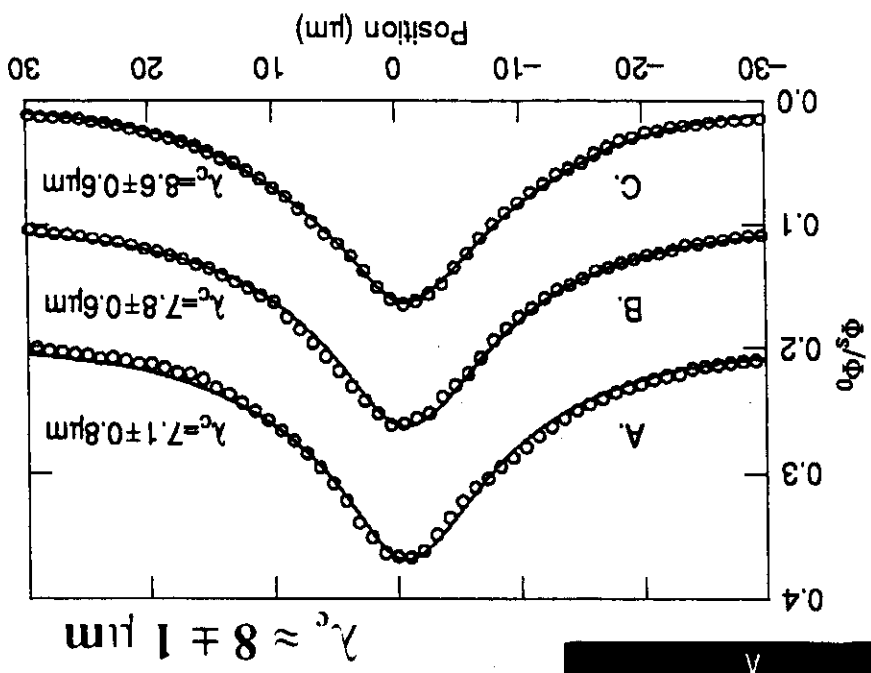
c-axis resistivity of $(\text{Hg,Cu})\text{Ba}_2\text{CuO}_{4+\delta}$





0.55 ϕ_0

0.2 ϕ_0



c-axis penetration depths in ^{nominally} optimally doped single-layer cuprates

	LSCO	Hg-1201	Tl-2201
λ_{ILT}	$\sim 3\mu\text{m}$ [Anderson*]	$\sim 1\mu\text{m}$ [Anderson†]	$\sim 1\mu\text{m}$ [Anderson*]
vortex imaging	$\sim 5\mu\text{m}$ [us]	$8\pm 1\mu\text{m}$ [us]	$18\pm 3\mu\text{m}$ [us]
optical ($1/\omega$)	$4\frac{1}{2}\mu\text{m}$ [Uchida]	$6\mu\text{m}$ [Basov]	$12\mu\text{m}$ [Basov]
optical (sum rule)			
optical (ω_p)			$17\mu\text{m}$ [van der Marel]
microwave	$4\mu\text{m}$ [Shibauchi]		
oriented powder susceptibility		$1.36\pm 0.16\mu\text{m}^\dagger$ [Panagopoulos]	
$\eta \approx \left(\frac{\lambda_{ILT}}{\lambda_c}\right)^2$	$\eta \approx 1$	$\eta \approx 10^{-2}$	$\eta \approx 10^{-3}$

*C_p by Loram

†C_p by Charalambous

†slightly overdoped

The ILT mechanism can only supply 1% of the condensation energy in the two highest-T_c single-layer cuprates.

caveats

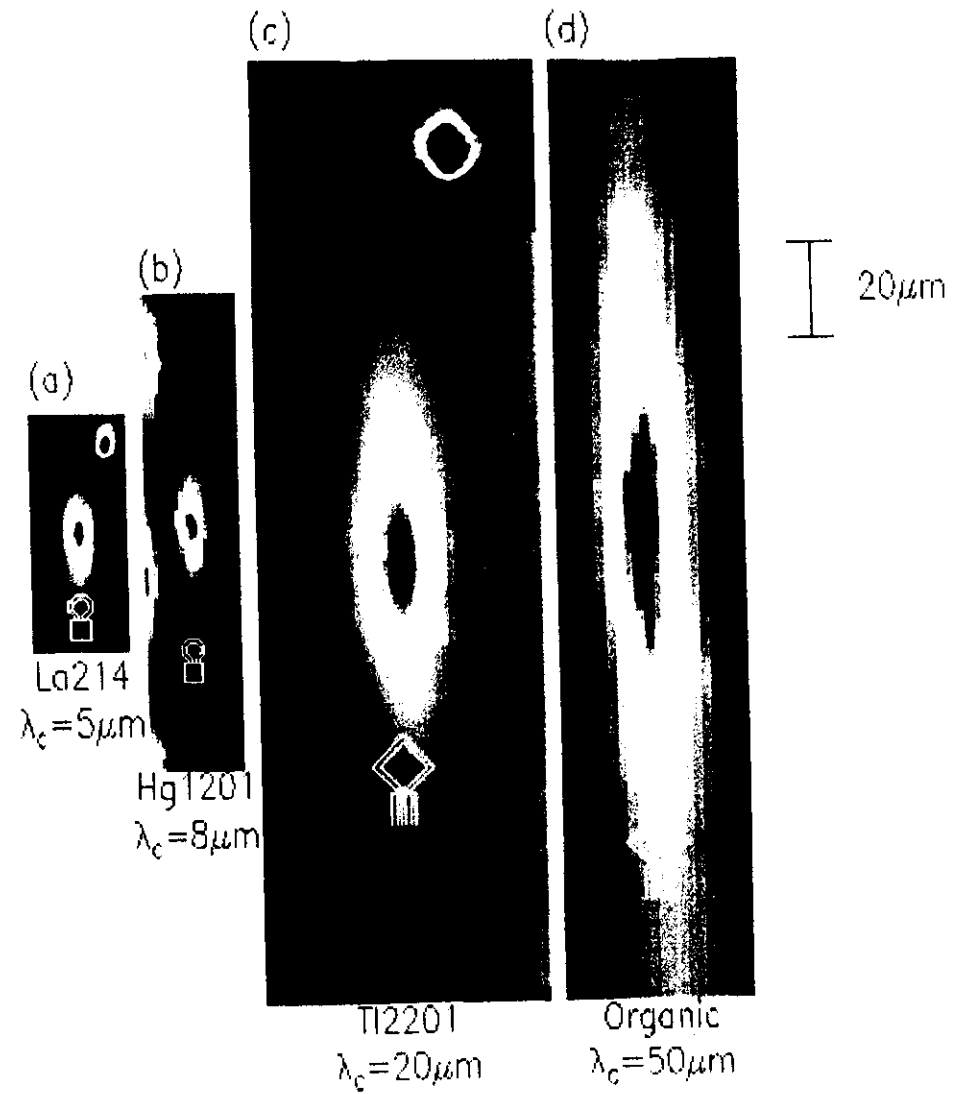
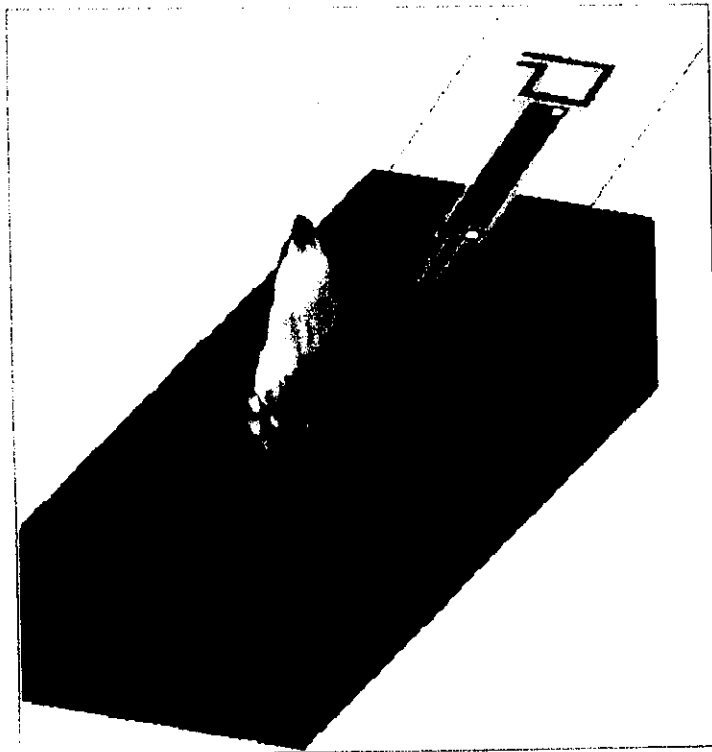
“Conventional” estimates for λ_c

Tl-2201

- Diffusive transmission $\lambda_c \approx 1-6 \mu\text{m}$
(parallel momentum not conserved)
- Diffusive + *d*-wave $\lambda_c > 1-6 \mu\text{m}$
(or other anisotropic gap)
Graf, Rainer, and Sauls
Rojo and Levin
Hirschfeld, Quinlan, and Scalapino
- Specular transmission $\lambda_c \approx 1 \mu\text{m}$
(parallel momentum conserved)
Bulaevskii
- Das Sarma and Hwang $\omega_p = 30 \text{ cm}^{-1}$
(elastic scattering, *d*-wave, realistic band structure)

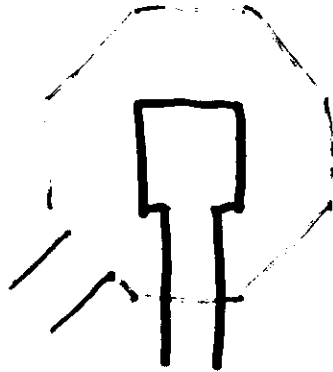
Interlayer penetration depths

28

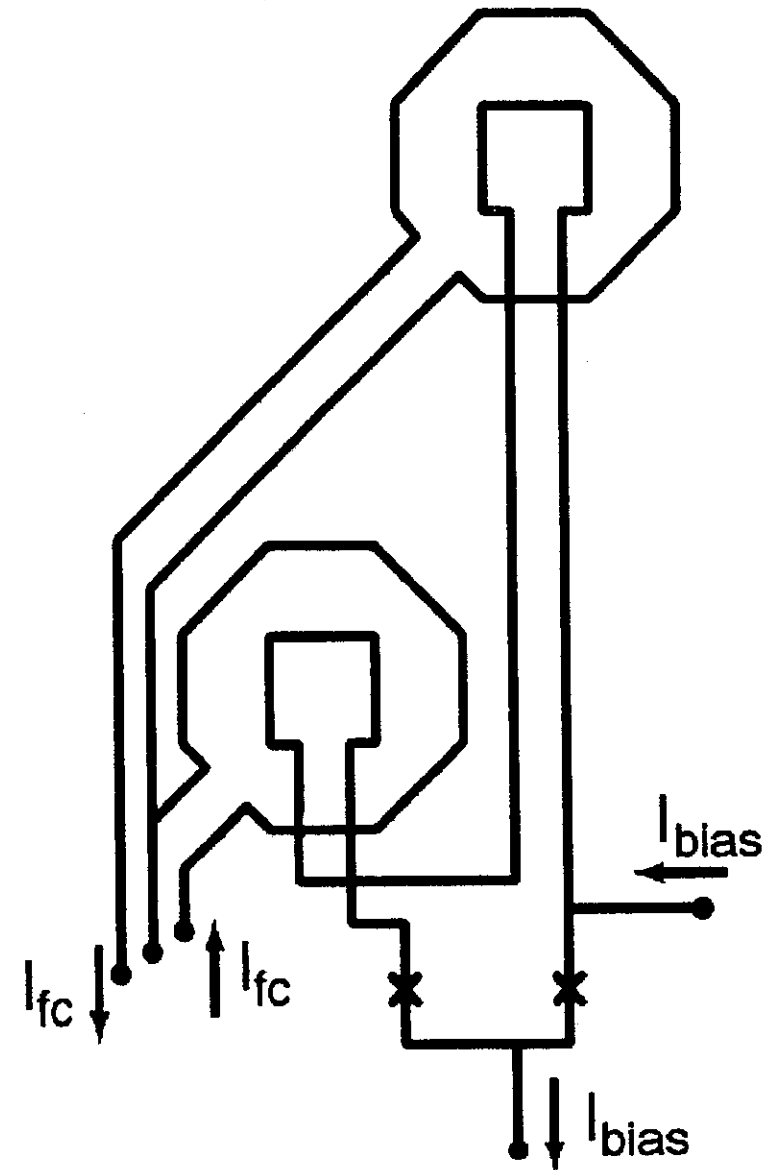
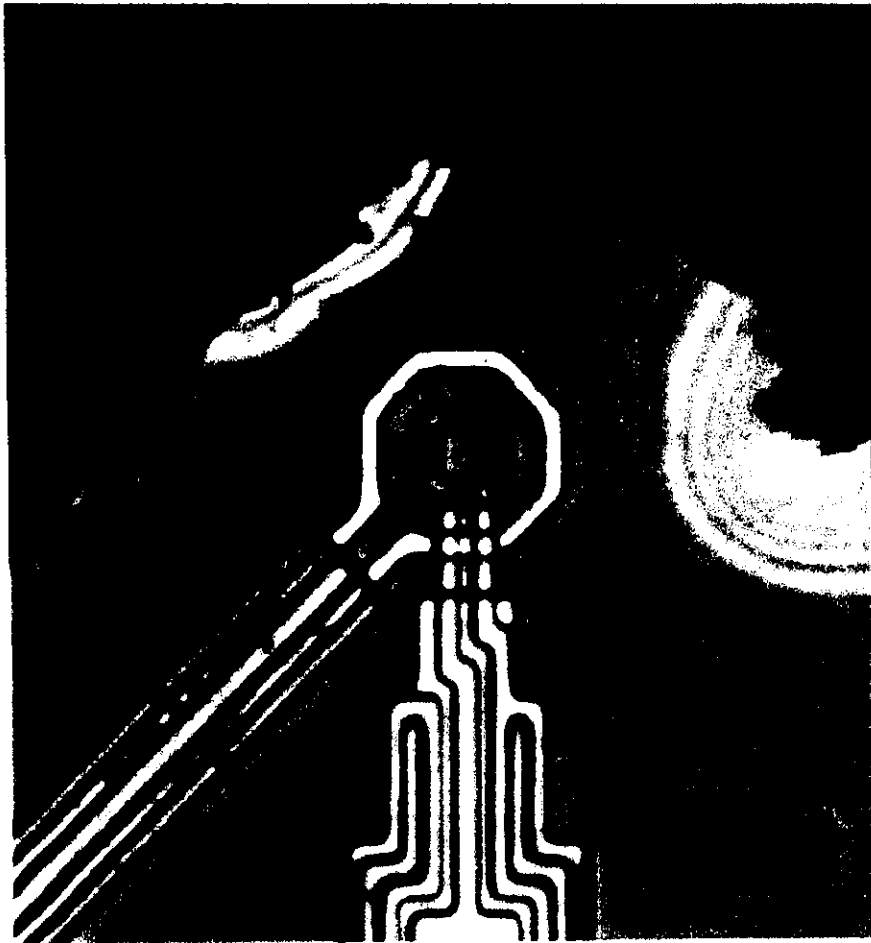


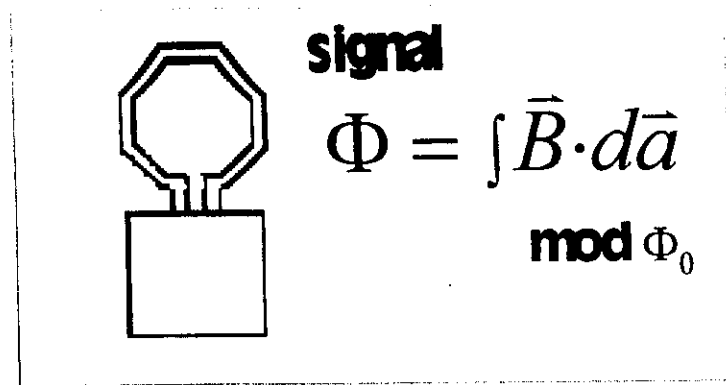
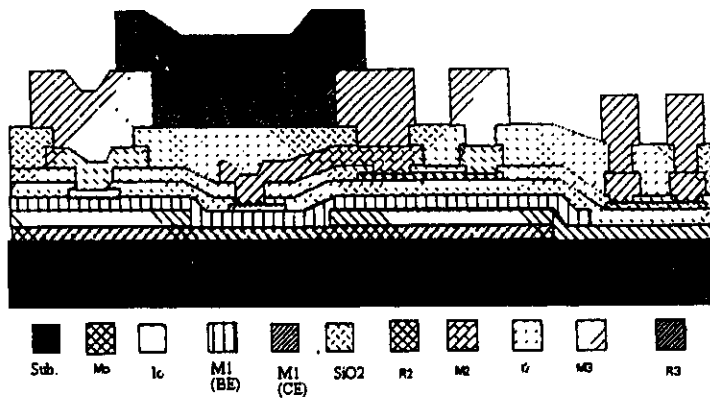
μ -SQUID Susceptometry

- Measurements of individual mesoscopic samples
- Local characterization of macroscopic samples

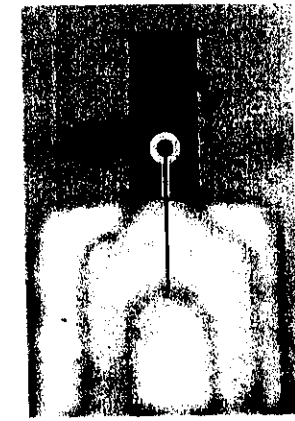
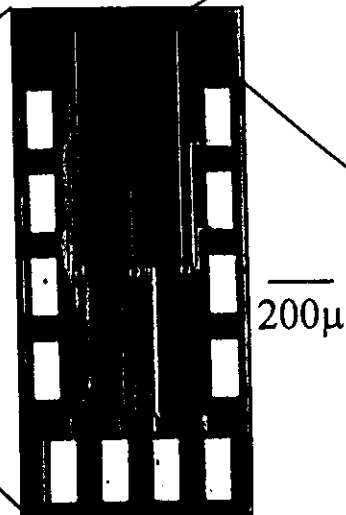
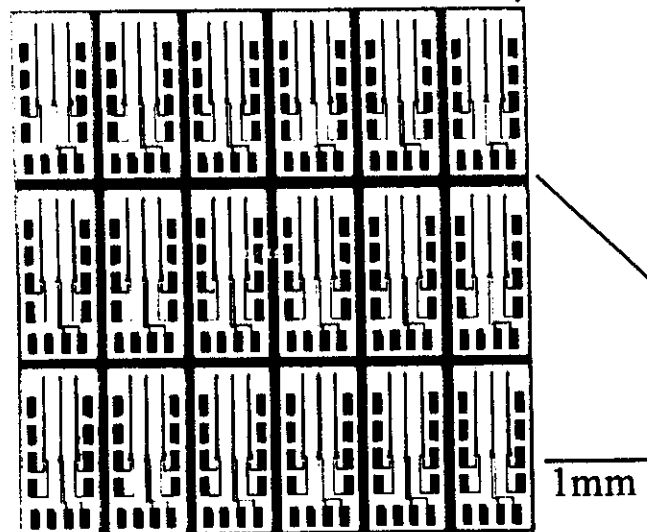


Scanning SQUID Susceptometry





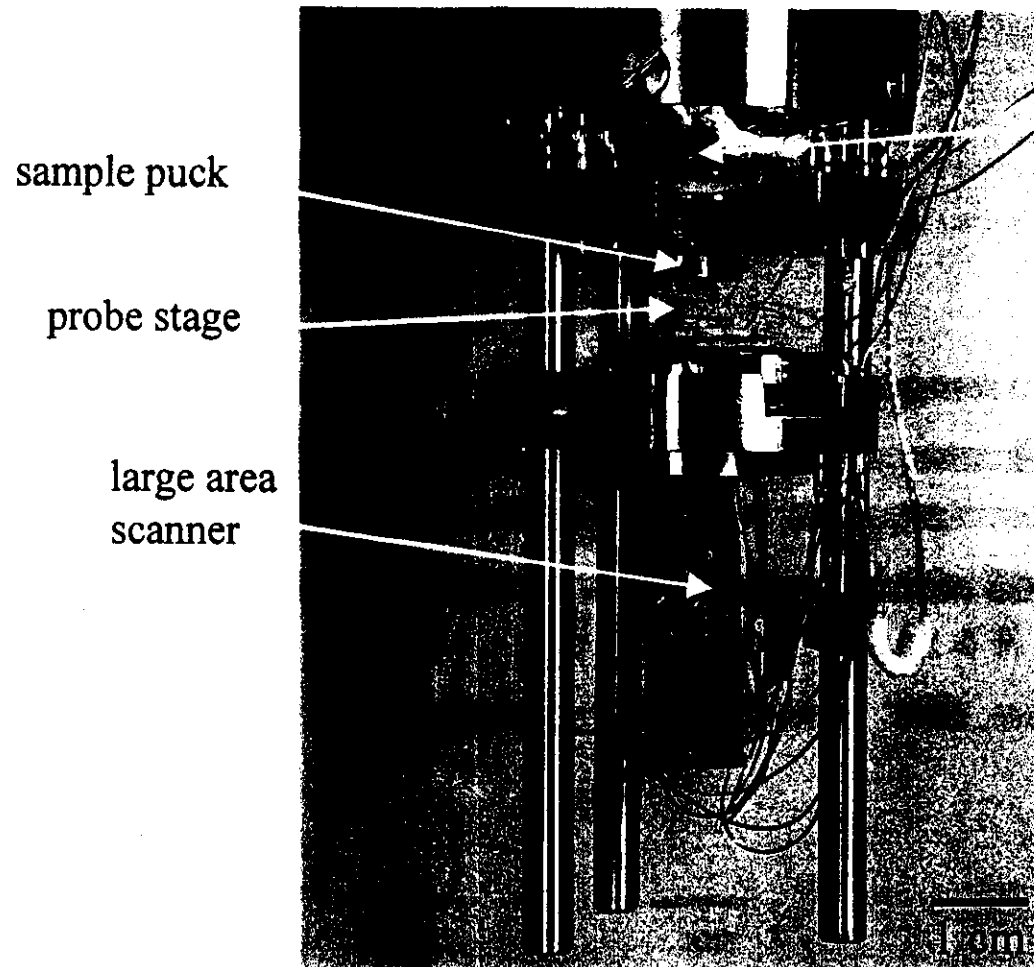
Nb SQUID Fabrication at HYPRES and SNF



Final submicron etch
at Stanford

SQUID Designs: IBM Joint Study Agreement
SNF Fabrication: Per Bjornsson, Adrian Lu

The Scanning Microscope

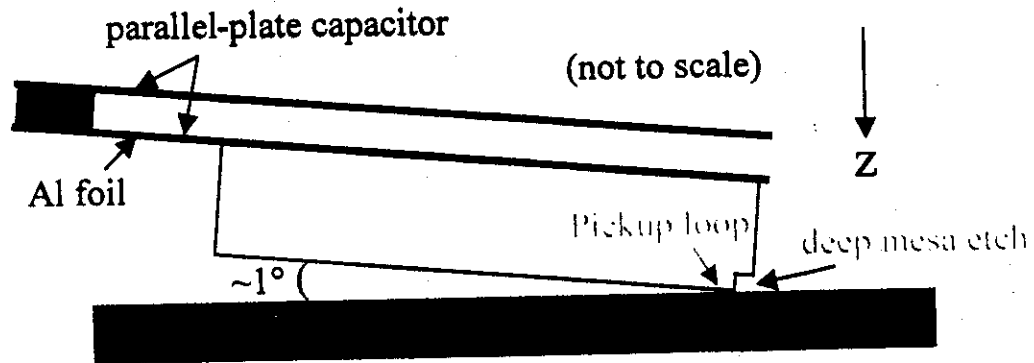


piezoelectric
tube scanner
with inertial stick
slip coarse motion

Large Area Scanner:

- piezoelectric S-bender design
- $70 \times 70 \mu\text{m}^2$ scan area at 4 K
- vib. noise $\sim 1 \text{ \AA}$

Scanning SQUID



- Pickup loop is approx. $3\ \mu\text{m}$ above sample
- Capacitor provides Z information

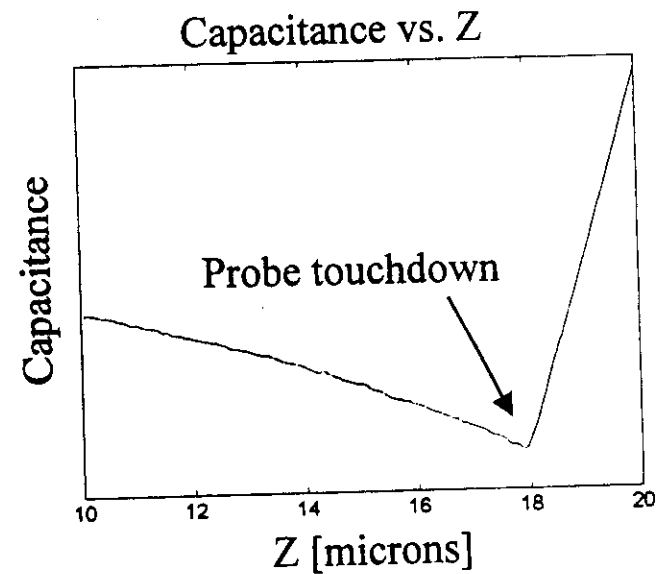
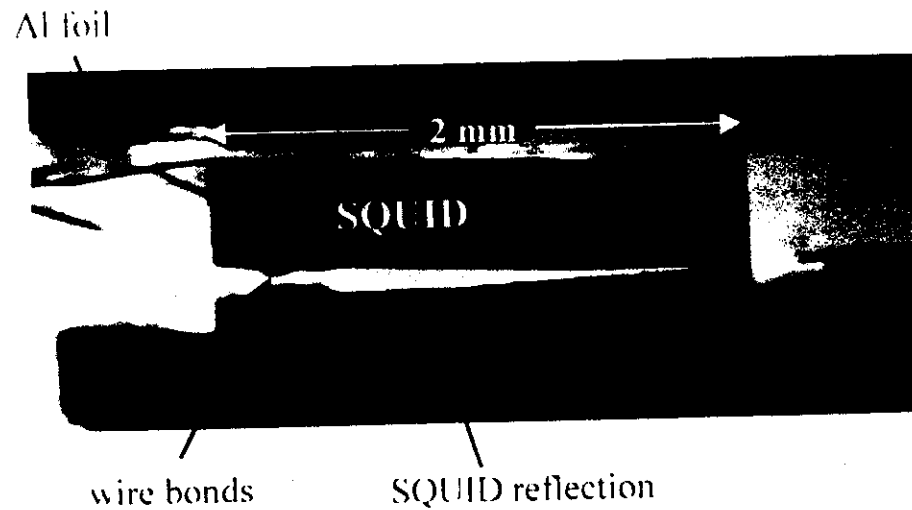
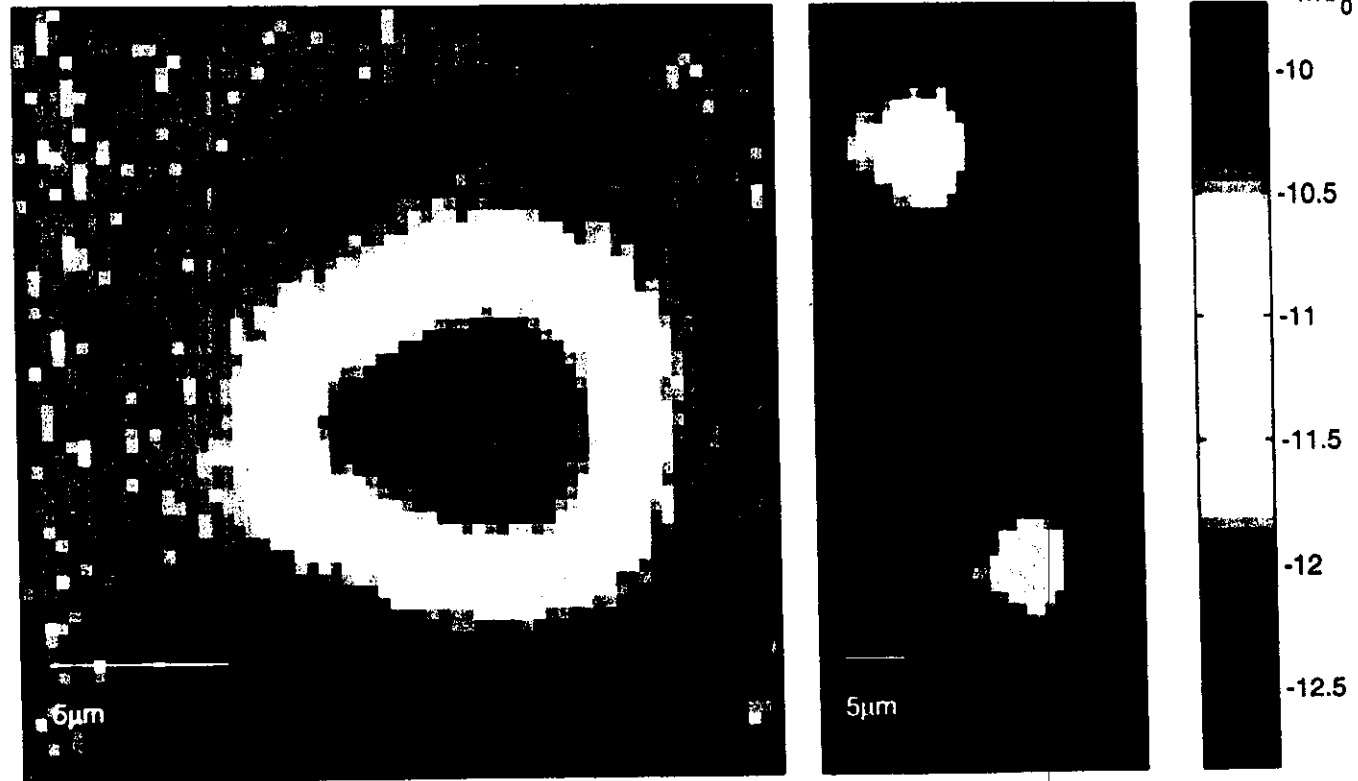


Image of an array of tin disks at 2.3K

34



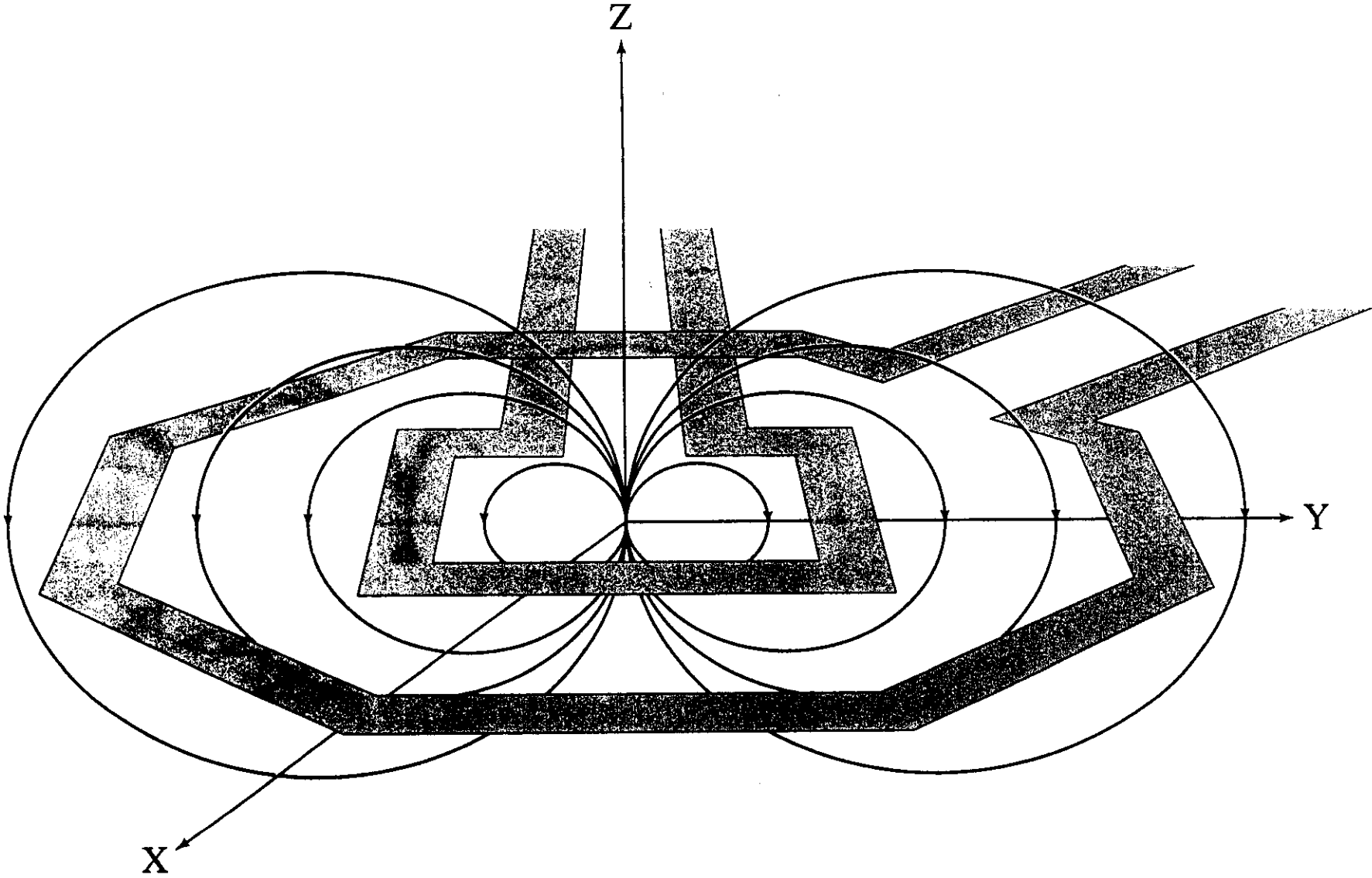
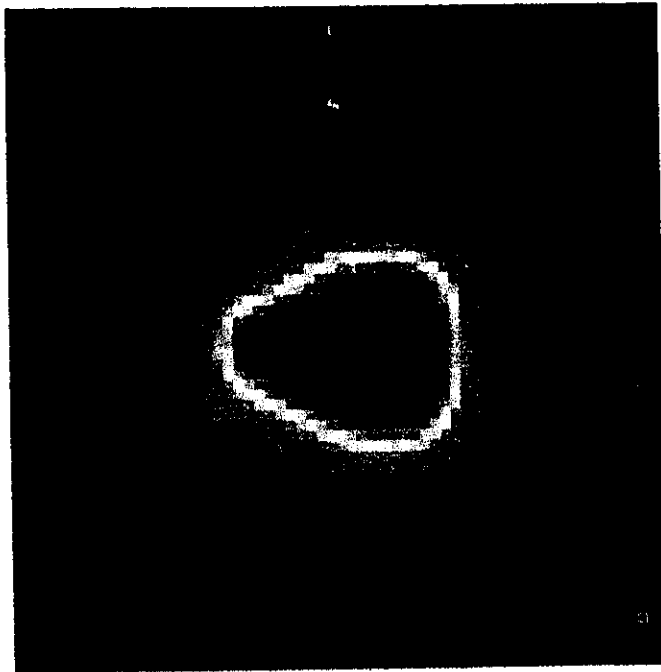
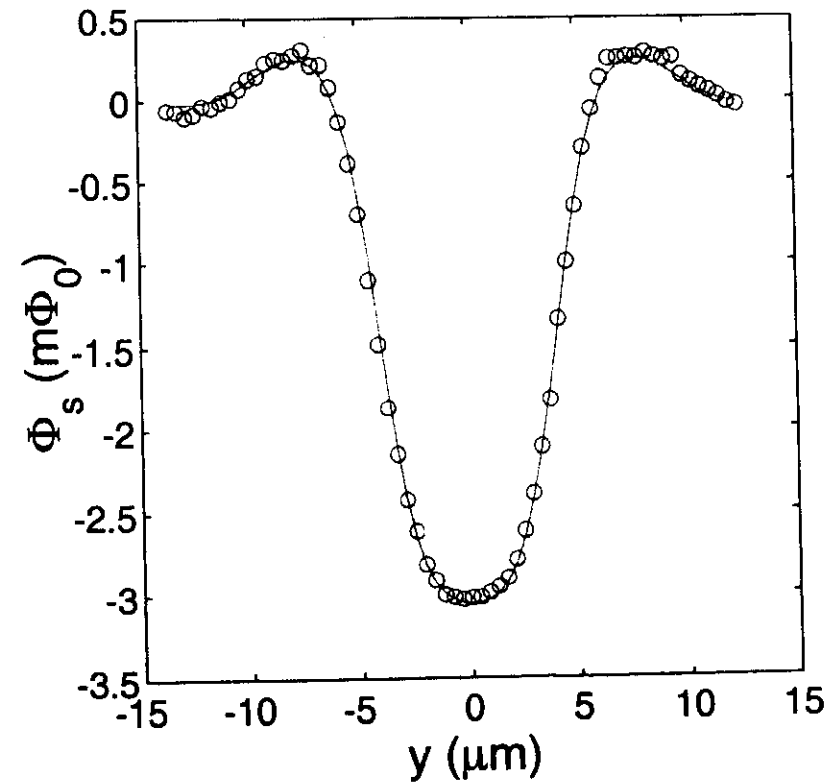


Image of a 3μ tin disk at 2.7 K



$$I_a = 0.44 \text{ mA} \\ \Rightarrow H_a \approx 0.25 \text{ G}$$



$$\frac{dm}{dH_a} = 3.65 \times 10^7 \mu_B / \text{G}$$

min sensitivity $1 \times 10^5 \mu_B / \mu\text{m}$

Scanning SQUID Susceptometry

- Spin Sensitivity $1 \times 10^5 \mu_B / \sqrt{\text{Hz}}$

Can be improved to $10^3 \mu_B / \sqrt{\text{Hz}}$ with current sensors

Can theoretically be improved to $1 \mu_B / \sqrt{\text{Hz}}$
with subsequent generations

- Spatial Resolution $8 \mu\text{m}$

Can be improved to $\sim 0.5 \mu\text{m}$ with
subsequent generations.

